

## DMOS DRIVER FOR BIPOLAR STEPPER MOTOR

- OPERATING SUPPLY VOLTAGE FROM 8 TO 52V
- 5.6A OUTPUT PEAK CURRENT (2.8A RMS)
- $R_{DS(ON)}$  0.3Ω TYP. VALUE @  $T_j = 25^\circ\text{C}$
- OPERATING FREQUENCY UP TO 100kHz
- NON DISSIPATIVE OVERCURRENT PROTECTION
- DUAL INDEPENDENT CONSTANT  $t_{OFF}$  PWM CURRENT CONTROLLERS
- FAST/SLOW DECAY MODE SELECTION
- FAST DECAY QUASI-SYNCHRONOUS RECTIFICATION
- DECODING LOGIC FOR STEPPER MOTOR FULL AND HALF STEP DRIVE
- CROSS CONDUCTION PROTECTION
- THERMAL SHUTDOWN
- UNDER VOLTAGE LOCKOUT
- INTEGRATED FAST FREE WHEELING DIODES

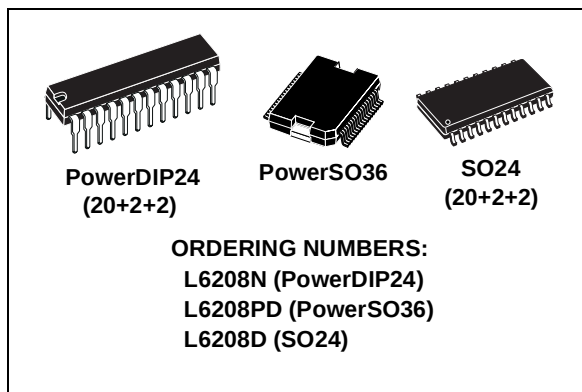
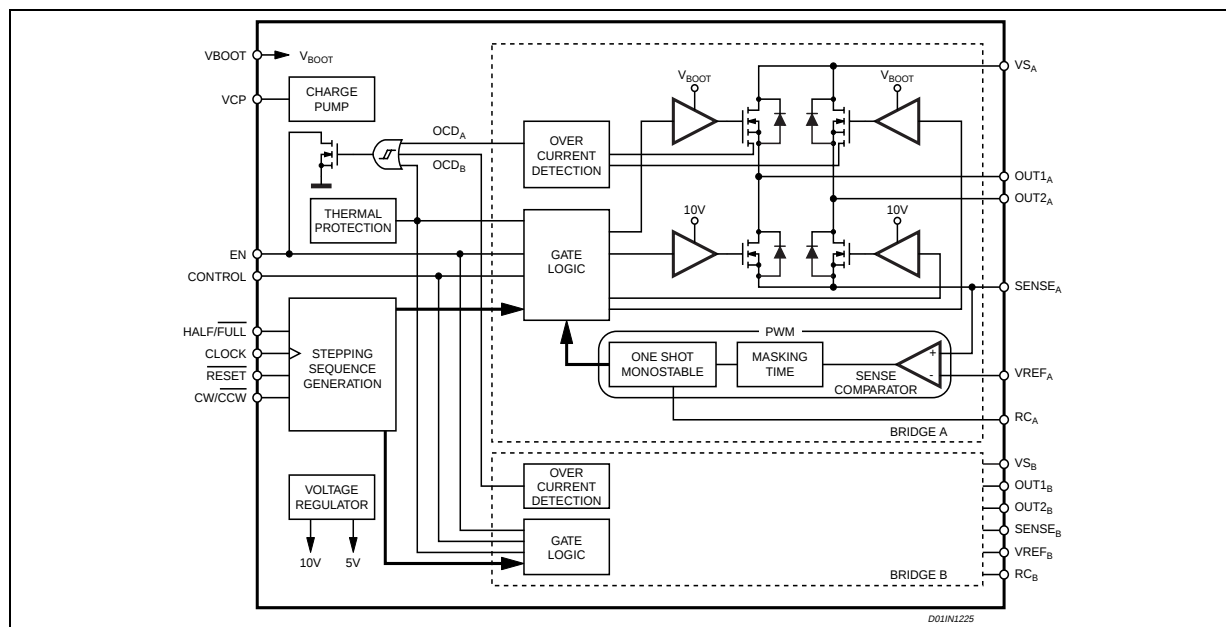
### TYPICAL APPLICATIONS

- BIPOLAR STEPPER MOTOR

### DESCRIPTION

The L6208 is a DMOS Fully Integrated Stepper Motor Driver with non-dissipative Overcurrent Protection, realized in MultiPower-BCD technology, which com-

### BLOCK DIAGRAM



bines isolated DMOS Power Transistors with CMOS and bipolar circuits on the same chip. The device includes all the circuitry needed to drive a two-phase bipolar stepper motor including: a dual DMOS Full Bridge, the constant off time PWM Current Controller that performs the chopping regulation and the Phase Sequence Generator, that generates the stepping sequence. Available in PowerDIP24 (20+2+2), PowerSO36 and SO24 (20+2+2) packages, the L6208 features a non-dissipative overcurrent protection on the high side Power MOSFETs and thermal shutdown.

## ABSOLUTE MAXIMUM RATINGS

| Symbol                         | Parameter                                                                                        | Test conditions                                                    | Value      | Unit |
|--------------------------------|--------------------------------------------------------------------------------------------------|--------------------------------------------------------------------|------------|------|
| $V_S$                          | Supply Voltage                                                                                   | $V_{SA} = V_{SB} = V_S$                                            | 60         | V    |
| $V_{OD}$                       | Differential Voltage between $V_{SA}$ , OUT1A, OUT2A, SENSEA and $V_{SB}$ , OUT1B, OUT2B, SENSEB | $V_{SA} = V_{SB} = V_S = 60V$ ;<br>$V_{SENSEA} = V_{SENSEB} = GND$ | 60         | V    |
| $V_{BOOT}$                     | Bootstrap Peak Voltage                                                                           | $V_{SA} = V_{SB} = V_S$                                            | $V_S + 10$ | V    |
| $V_{IN}, V_{EN}$               | Input and Enable Voltage Range                                                                   |                                                                    | -0.3 to +7 | V    |
| $V_{REFA}$ ,<br>$V_{REFB}$     | Voltage Range at pins $V_{REFA}$ and $V_{REFB}$                                                  |                                                                    | -0.3 to +7 | V    |
| $V_{RCA}$ , $V_{RCB}$          | Voltage Range at pins $RC_A$ and $RC_B$                                                          |                                                                    | -0.3 to +7 | V    |
| $V_{SENSEA}$ ,<br>$V_{SENSEB}$ | Voltage Range at pins SENSEA and SENSEB                                                          |                                                                    | -1 to +4   | V    |
| $I_{S(peak)}$                  | Pulsed Supply Current (for each $V_S$ pin), internally limited by the overcurrent protection     | $V_{SA} = V_{SB} = V_S$ ;<br>$t_{PULSE} < 1ms$                     | 7.1        | A    |
| $I_S$                          | RMS Supply Current (for each $V_S$ pin)                                                          | $V_{SA} = V_{SB} = V_S$                                            | 2.8        | A    |
| $T_{stg}, T_{OP}$              | Storage and Operating Temperature Range                                                          |                                                                    | -40 to 150 | °C   |

## RECOMMENDED OPERATING CONDITIONS

| Symbol                         | Parameter                                                                                        | Test Conditions                                        | MIN      | MAX    | Unit   |
|--------------------------------|--------------------------------------------------------------------------------------------------|--------------------------------------------------------|----------|--------|--------|
| $V_S$                          | Supply Voltage                                                                                   | $V_{SA} = V_{SB} = V_S$                                | 8        | 52     | V      |
| $V_{OD}$                       | Differential Voltage Between $V_{SA}$ , OUT1A, OUT2A, SENSEA and $V_{SB}$ , OUT1B, OUT2B, SENSEB | $V_{SA} = V_{SB} = V_S$ ;<br>$V_{SENSEA} = V_{SENSEB}$ |          | 52     | V      |
| $V_{REFA}$ ,<br>$V_{REFB}$     | Voltage Range at pins $V_{REFA}$ and $V_{REFB}$                                                  |                                                        | -0.1     | 5      | V      |
| $V_{SENSEA}$ ,<br>$V_{SENSEB}$ | Voltage Range at pins SENSEA and SENSEB                                                          | (pulsed $t_W < t_{rr}$ )<br>(DC)                       | -6<br>-1 | 6<br>1 | V<br>V |
| $I_{OUT}$                      | RMS Output Current                                                                               |                                                        |          | 2.8    | A      |
| $T_j$                          | Operating Junction Temperature                                                                   |                                                        | -25      | +125   | °C     |
| $f_{sw}$                       | Switching Frequency                                                                              |                                                        |          | 100    | KHz    |

## THERMAL DATA

| Symbol          | Description                                                | PowerDIP24 | SO24 | PowerSO36 | Unit |
|-----------------|------------------------------------------------------------|------------|------|-----------|------|
| $R_{th-j-pins}$ | Maximum Thermal Resistance Junction-Pins                   | 18         | 14   | -         | °C/W |
| $R_{th-j-case}$ | Maximum Thermal Resistance Junction-Case                   | -          | -    | 1         | °C/W |
| $R_{th-j-amb1}$ | Maximum Thermal Resistance Junction-Ambient <sup>(1)</sup> | 43         | 51   | -         | °C/W |
| $R_{th-j-amb1}$ | Maximum Thermal Resistance Junction-Ambient <sup>(2)</sup> | -          | -    | 35        | °C/W |
| $R_{th-j-amb1}$ | Maximum Thermal Resistance Junction-Ambient <sup>(3)</sup> | -          | -    | 15        | °C/W |
| $R_{th-j-amb2}$ | Maximum Thermal Resistance Junction-Ambient <sup>(4)</sup> | 58         | 77   | 62        | °C/W |

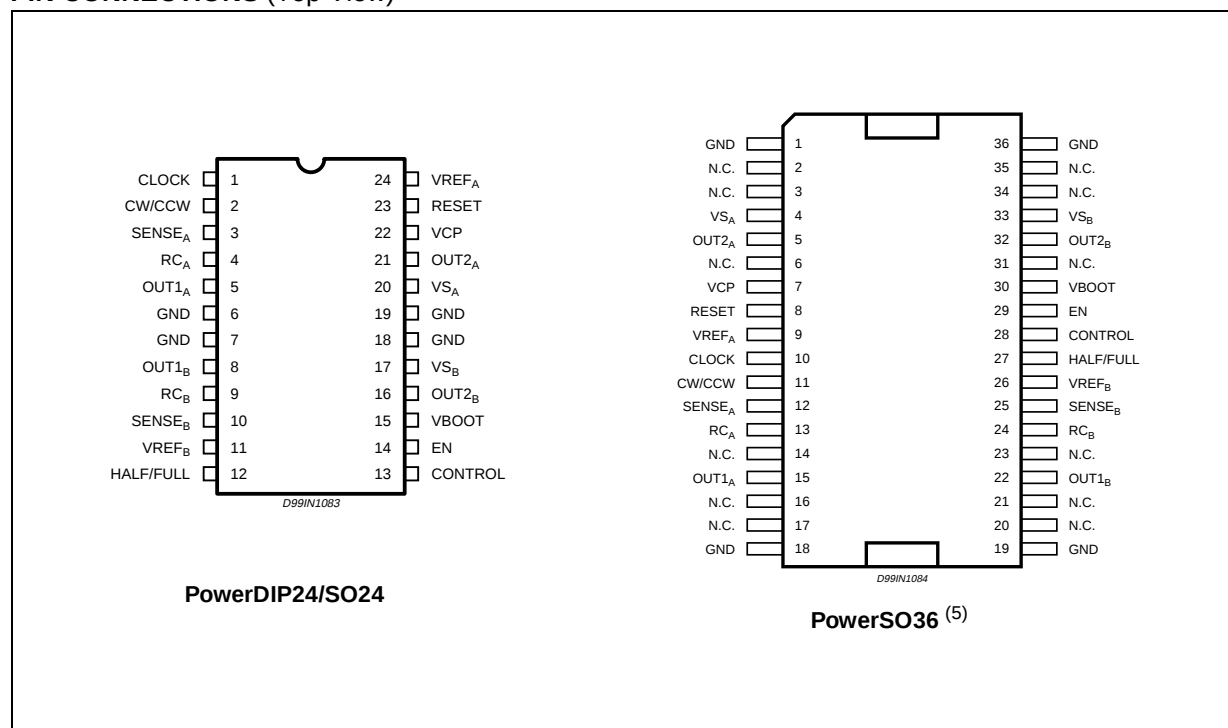
(1) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the bottom side of 6cm<sup>2</sup> (with a thickness of 35µm).

(2) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the top side of 6cm<sup>2</sup> (with a thickness of 35µm).

(3) Mounted on a multi-layer FR4 PCB with a dissipating copper surface on the top side of 6cm<sup>2</sup> (with a thickness of 35µm), 16 via holes and a ground layer.

(4) Mounted on a multi-layer FR4 PCB without any heat sinking surface on the board.

## PIN CONNECTIONS (Top View)



(5) The slug is internally connected to pins 1, 18, 19 and 36 (GND pins).

## PIN DESCRIPTION

| PACKAGE             |                  | Name               | Type                       | Function                                                                                                                                                                                                                                                                                 |
|---------------------|------------------|--------------------|----------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SO24/<br>PowerDIP24 | PowerSO36        |                    |                            |                                                                                                                                                                                                                                                                                          |
| PIN #               | PIN #            |                    |                            |                                                                                                                                                                                                                                                                                          |
| 1                   | 10               | CLOCK              | Logic Input                | Step Clock input. The state machine makes one step on each rising edge.                                                                                                                                                                                                                  |
| 2                   | 11               | CW/CCW             | Logic Input                | Selects the direction of the rotation. HIGH logic level sets clockwise direction, whereas LOW logic level sets counterclockwise direction.<br>If not used, it has to be connected to GND or +5V.                                                                                         |
| 3                   | 12               | SENSE <sub>A</sub> | Power Supply               | Bridge A Source Pin. This pin must be connected to Power Ground through a sensing power resistor.                                                                                                                                                                                        |
| 4                   | 13               | RC <sub>A</sub>    | RC Pin                     | RC Network Pin. A parallel RC network connected between this pin and ground sets the Current Controller OFF-Time of the Bridge A.                                                                                                                                                        |
| 5                   | 15               | OUT1 <sub>A</sub>  | Power Output               | Bridge A Output 1.                                                                                                                                                                                                                                                                       |
| 6, 7,<br>18, 19     | 1, 18,<br>19, 36 | GND                | GND                        | Ground terminals. In PowerDIP24 and SO24 packages, these pins are also used for heat dissipation toward the PCB. On PowerSO36 package the slug is connected to these pins.                                                                                                               |
| 8                   | 22               | OUT1 <sub>B</sub>  | Power Output               | Bridge B Output 1.                                                                                                                                                                                                                                                                       |
| 9                   | 24               | RC <sub>B</sub>    | RC Pin                     | RC Network Pin. A parallel RC network connected between this pin and ground sets the Current Controller OFF-Time of the Bridge B.                                                                                                                                                        |
| 10                  | 25               | SENSE <sub>B</sub> | Power Supply               | Bridge B Source Pin. This pin must be connected to Power Ground through a sensing power resistor.                                                                                                                                                                                        |
| 11                  | 26               | VREF <sub>B</sub>  | Analog Input               | Bridge B Current Controller Reference Voltage.<br>Do not leave this pin open or connected to GND.                                                                                                                                                                                        |
| 12                  | 27               | HALF/FULL          | Logic Input                | Step Mode Selector. HIGH logic level sets HALF STEP Mode, LOW logic level sets FULL STEP Mode.<br>If not used, it has to be connected to GND or +5V.                                                                                                                                     |
| 13                  | 28               | CONTROL            | Logic Input                | Decay Mode Selector. HIGH logic level sets SLOW DECAY Mode, LOW logic level sets FAST DECAY Mode.<br>If not used, it has to be connected to GND or +5V.                                                                                                                                  |
| 14                  | 29               | EN                 | Logic Input <sup>(6)</sup> | Chip Enable. LOW logic level switches OFF all Power MOSFETs of both Bridge A and Bridge B. This pin is also connected to the collector of the Overcurrent and Thermal Protection to implement over current protection.<br>If not used, it has to be connected to +5V through a resistor. |
| 15                  | 30               | VBOOT              | Supply Voltage             | Bootstrap Voltage needed for driving the upper Power MOSFETs of both Bridge A and Bridge B.                                                                                                                                                                                              |
| 16                  | 32               | OUT2 <sub>B</sub>  | Power Output               | Bridge B Output 2.                                                                                                                                                                                                                                                                       |
| 17                  | 33               | VS <sub>B</sub>    | Power Supply               | Bridge B Power Supply Voltage. It must be connected to the Supply Voltage together with pin VS <sub>A</sub>                                                                                                                                                                              |
| 20                  | 4                | VS <sub>A</sub>    | Power Supply               | Bridge A Power Supply Voltage. It must be connected to the Supply Voltage together with pin VS <sub>B</sub>                                                                                                                                                                              |

## PIN DESCRIPTION (continued)

| PACKAGE             |           | Name              | Type         | Function                                                                                                                                                          |
|---------------------|-----------|-------------------|--------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SO24/<br>PowerDIP24 | PowerSO36 |                   |              |                                                                                                                                                                   |
| PIN #               | PIN #     |                   |              |                                                                                                                                                                   |
| 21                  | 5         | OUT2 <sub>A</sub> | Power Output | Bridge A Output 2.                                                                                                                                                |
| 22                  | 7         | VCP               | Output       | Charge Pump Oscillator Output.                                                                                                                                    |
| 23                  | 8         | RESET             | Logic Input  | Reset Pin. LOW logic level restores the <i>Home</i> State (State 1) on the Phase Sequence Generator State Machine.<br>If not used, it has to be connected to +5V. |
| 24                  | 9         | VREF <sub>A</sub> | Analog Input | Bridge A Current Controller Reference Voltage.<br>Do not leave this pin open or connected to GND.                                                                 |

- (6) Also connected at the output drain of the Over current and Thermal protection MOSFET. Therefore, it has to be driven putting in series a resistor with a value in the range of 2.2K $\Omega$  - 180K $\Omega$ , recommended 100K $\Omega$ .

## ELECTRICAL CHARACTERISTICS

(T<sub>amb</sub> = 25°C, V<sub>S</sub> = 48V, unless otherwise specified)

| Symbol                | Parameter                    | Test Conditions                                                    | Min | Typ | Max | Unit |
|-----------------------|------------------------------|--------------------------------------------------------------------|-----|-----|-----|------|
| V <sub>Sth(ON)</sub>  | Turn-on Threshold            |                                                                    | 6.6 | 7   | 7.4 | V    |
| V <sub>Sth(OFF)</sub> | Turn-off Threshold           |                                                                    | 5.6 | 6   | 6.4 | V    |
| I <sub>S</sub>        | Quiescent Supply Current     | All Bridges OFF;<br>T <sub>j</sub> = -25°C to 125°C <sup>(7)</sup> |     | 5   | 10  | mA   |
| T <sub>j(OFF)</sub>   | Thermal Shutdown Temperature |                                                                    |     | 165 |     | °C   |

## Output DMOS Transistors

|                     |                                |                                        |       |      |      |          |
|---------------------|--------------------------------|----------------------------------------|-------|------|------|----------|
| R <sub>DS(ON)</sub> | High-Side Switch ON Resistance | T <sub>j</sub> = 25 °C                 |       | 0.34 | 0.4  | $\Omega$ |
|                     |                                | T <sub>j</sub> = 125 °C <sup>(7)</sup> |       | 0.53 | 0.59 | $\Omega$ |
|                     | Low-Side Switch ON Resistance  | T <sub>j</sub> = 25 °C                 |       | 0.28 | 0.34 | $\Omega$ |
|                     |                                | T <sub>j</sub> = 125 °C <sup>(7)</sup> |       | 0.47 | 0.53 | $\Omega$ |
| I <sub>DSS</sub>    | Leakage Current                | EN = Low; OUT = V <sub>S</sub>         |       |      | 2    | mA       |
|                     |                                | EN = Low; OUT = GND                    | -0.15 |      |      | mA       |

## Source Drain Diodes

|                 |                       |                                  |  |      |     |    |
|-----------------|-----------------------|----------------------------------|--|------|-----|----|
| V <sub>SD</sub> | Forward ON Voltage    | I <sub>SD</sub> = 2.8A, EN = LOW |  | 1.15 | 1.3 | V  |
| t <sub>rr</sub> | Reverse Recovery Time | I <sub>f</sub> = 2.8A            |  | 300  |     | ns |
| t <sub>fr</sub> | Forward Recovery Time |                                  |  | 200  |     | ns |

## Logic Inputs (EN, CONTROL, HALF/FULL, CLOCK, RESET, CW/CCW)

|                 |                                |  |      |  |     |   |
|-----------------|--------------------------------|--|------|--|-----|---|
| V <sub>IL</sub> | Low level logic input voltage  |  | -0.3 |  | 0.8 | V |
| V <sub>IH</sub> | High level logic input voltage |  | 2    |  | 7   | V |

**ELECTRICAL CHARACTERISTICS** (continued)(T<sub>amb</sub> = 25°C, V<sub>S</sub> = 48V, unless otherwise specified)

| Symbol               | Parameter                      | Test Conditions         | Min  | Typ | Max | Unit |
|----------------------|--------------------------------|-------------------------|------|-----|-----|------|
| I <sub>IL</sub>      | Low Level Logic Input Current  | GND Logic Input Voltage | -10  |     |     | μA   |
| I <sub>IH</sub>      | High Level Logic Input Current | 7V Logic Input Voltage  |      |     | 10  | μA   |
| V <sub>th(ON)</sub>  | Turn-on Input Threshold        |                         |      | 1.8 | 2.0 | V    |
| V <sub>th(OFF)</sub> | Turn-off Input Threshold       |                         | 0.8  | 1.3 |     | V    |
| V <sub>th(HYS)</sub> | Input Threshold Hysteresis     |                         | 0.25 | 0.5 |     | V    |

**Switching Characteristics**

|                        |                                                     |                                                |     |     |     |     |
|------------------------|-----------------------------------------------------|------------------------------------------------|-----|-----|-----|-----|
| t <sub>D(ON)EN</sub>   | Enable to Output Turn-on Delay Time <sup>(8)</sup>  | I <sub>LOAD</sub> = 2.8A, Resistive Load       | 100 | 250 | 400 | ns  |
| t <sub>D(OFF)EN</sub>  | Enable to Output Turn-off Delay Time <sup>(8)</sup> | I <sub>LOAD</sub> = 2.8A, Resistive Load       | 300 | 550 | 800 | ns  |
| t <sub>RISE</sub>      | Output Rise Time <sup>(8)</sup>                     | I <sub>LOAD</sub> = 2.8A, Resistive Load       | 40  |     | 250 | ns  |
| t <sub>FALL</sub>      | Output Fall Time <sup>(8)</sup>                     | I <sub>LOAD</sub> = 2.8A, Resistive Load       | 40  |     | 250 | ns  |
| t <sub>DCLK</sub>      | Clock to Output Delay Time <sup>(9)</sup>           | I <sub>LOAD</sub> = 2.8A, Resistive Load       |     | 2   |     | μs  |
| t <sub>CLK(min)L</sub> | Minimum Clock Time <sup>(10)</sup>                  |                                                |     |     | 1   | μs  |
| t <sub>CLK(min)H</sub> | Minimum Clock Time <sup>(10)</sup>                  |                                                |     |     | 1   | μs  |
| f <sub>CLK</sub>       | Clock Frequency                                     |                                                |     |     | 100 | KHz |
| t <sub>S(MIN)</sub>    | Minimum Set-up Time <sup>(11)</sup>                 |                                                |     |     | 1   | μs  |
| t <sub>H(MIN)</sub>    | Minimum Hold Time <sup>(11)</sup>                   |                                                |     |     | 1   | μs  |
| t <sub>R(MIN)</sub>    | Minimum Reset Time <sup>(11)</sup>                  |                                                |     |     | 1   | μs  |
| t <sub>RCLK(MIN)</sub> | Minimum Reset to Clock Delay Time <sup>(11)</sup>   |                                                |     |     | 1   | μs  |
| t <sub>DT</sub>        | Dead Time Protection                                |                                                | 0.5 | 1   |     | μs  |
| f <sub>CP</sub>        | Charge Pump Frequency                               | T <sub>j</sub> = -25°C to 125°C <sup>(7)</sup> |     | 0.6 | 1   | MHz |

**PWM Compararator and Monostable**

|                                     |                                                            |                                              |     |     |   |    |
|-------------------------------------|------------------------------------------------------------|----------------------------------------------|-----|-----|---|----|
| I <sub>RCA</sub> , I <sub>RCB</sub> | Source Current at pins RC <sub>A</sub> and RC <sub>B</sub> | V <sub>RCA</sub> = V <sub>RCB</sub> = 2.5V   | 3.5 | 5.5 |   | mA |
| V <sub>offset</sub>                 | Offset Voltage on Sense Comparator                         | V <sub>REFA</sub> , V <sub>REFB</sub> = 0.5V |     | ±5  |   | mV |
| t <sub>PROP</sub>                   | Turn OFF Propagation Delay <sup>(12)</sup>                 |                                              |     | 500 |   | ns |
| t <sub>BLANK</sub>                  | Internal Blanking Time on SENSE pins                       |                                              |     | 1   |   | μs |
| t <sub>ON(MIN)</sub>                | Minimum On Time                                            |                                              |     | 1.5 | 2 | μs |

**ELECTRICAL CHARACTERISTICS** (continued)(T<sub>amb</sub> = 25°C, V<sub>S</sub> = 48V, unless otherwise specified)

| Symbol            | Parameter                                                          | Test Conditions                                  | Min | Typ | Max | Unit |
|-------------------|--------------------------------------------------------------------|--------------------------------------------------|-----|-----|-----|------|
| t <sub>OFF</sub>  | PWM Recirculation Time                                             | R <sub>OFF</sub> = 20KΩ; C <sub>OFF</sub> = 1nF  |     | 13  |     | μs   |
|                   |                                                                    | R <sub>OFF</sub> = 100KΩ; C <sub>OFF</sub> = 1nF |     | 61  |     | μs   |
| I <sub>BIAS</sub> | Input Bias Current at pins VREF <sub>A</sub> and VREF <sub>B</sub> |                                                  |     |     | 10  | μA   |

**Over Current Protection**

|                       |                                               |                                                |   |     |     |    |
|-----------------------|-----------------------------------------------|------------------------------------------------|---|-----|-----|----|
| I <sub>SOVER</sub>    | Input Supply Overcurrent Protection Threshold | T <sub>j</sub> = -25°C to 125°C <sup>(7)</sup> | 4 | 5.6 | 7.1 | A  |
| R <sub>OPDR</sub>     | Open Drain ON Resistance                      | I = 4mA                                        |   | 40  | 60  | Ω  |
| t <sub>OCD(ON)</sub>  | OCD Turn-on Delay Time (13)                   | I = 4mA; C <sub>EN</sub> < 100pF               |   | 200 |     | ns |
| t <sub>OCD(OFF)</sub> | OCD Turn-off Delay Time (13)                  | I = 4mA; C <sub>EN</sub> < 100pF               |   | 100 |     | ns |

(7) Tested at 25°C in a restricted range and guaranteed by characterization.

(8) See Fig. 1.

(9) See Fig. 2.

(10) See Fig. 3.

(11) See Fig. 4.

(12) Measured applying a voltage of 1V to pin SENSE and a voltage drop from 2V to 0V to pin VREF.

(13) See Fig. 5.

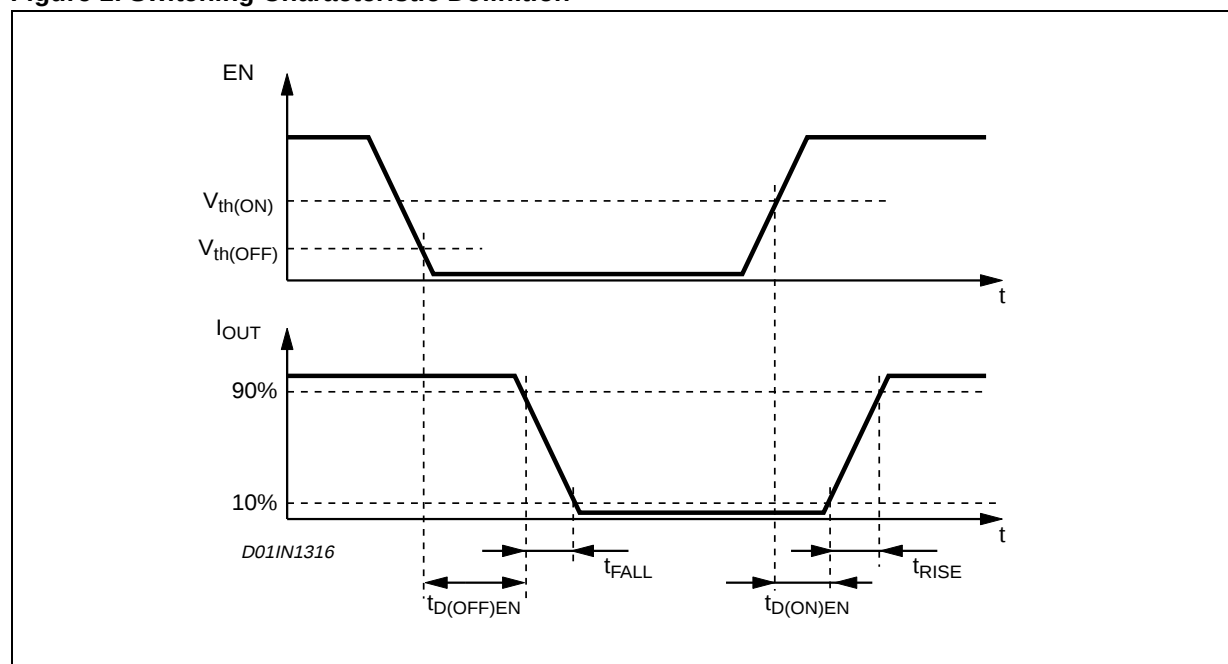
**Figure 1. Switching Characteristic Definition**

Figure 2. Clock to Output Delay Time

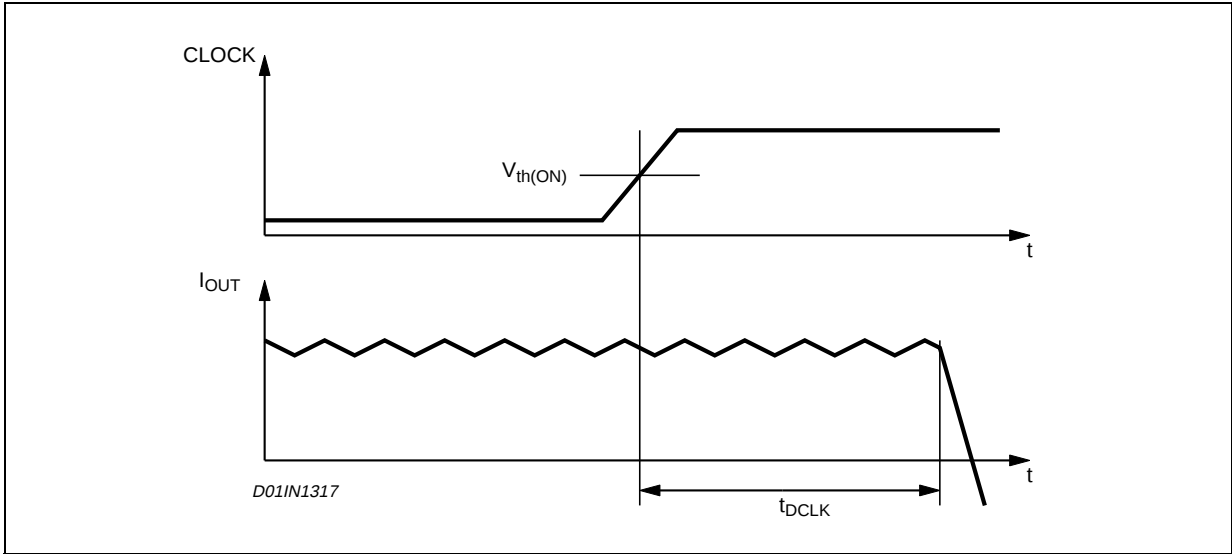


Figure 3. Minimum Timing Definition; Clock Input

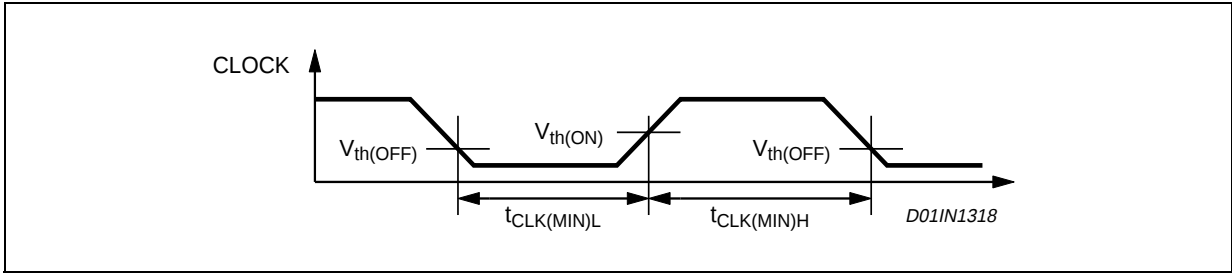


Figure 4. Minimum Timing Definition; Logic Inputs

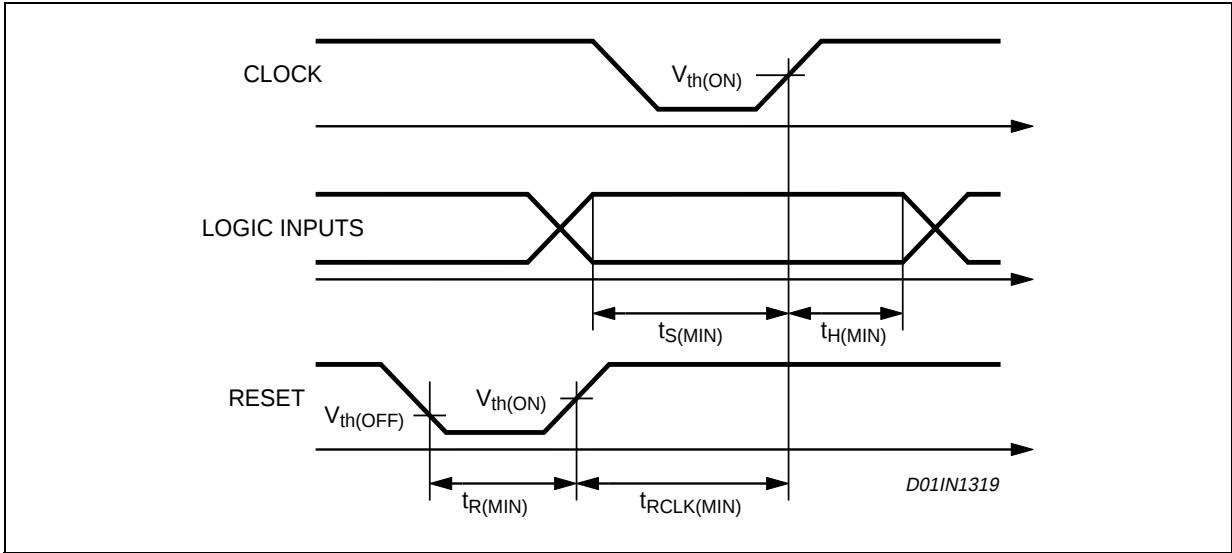
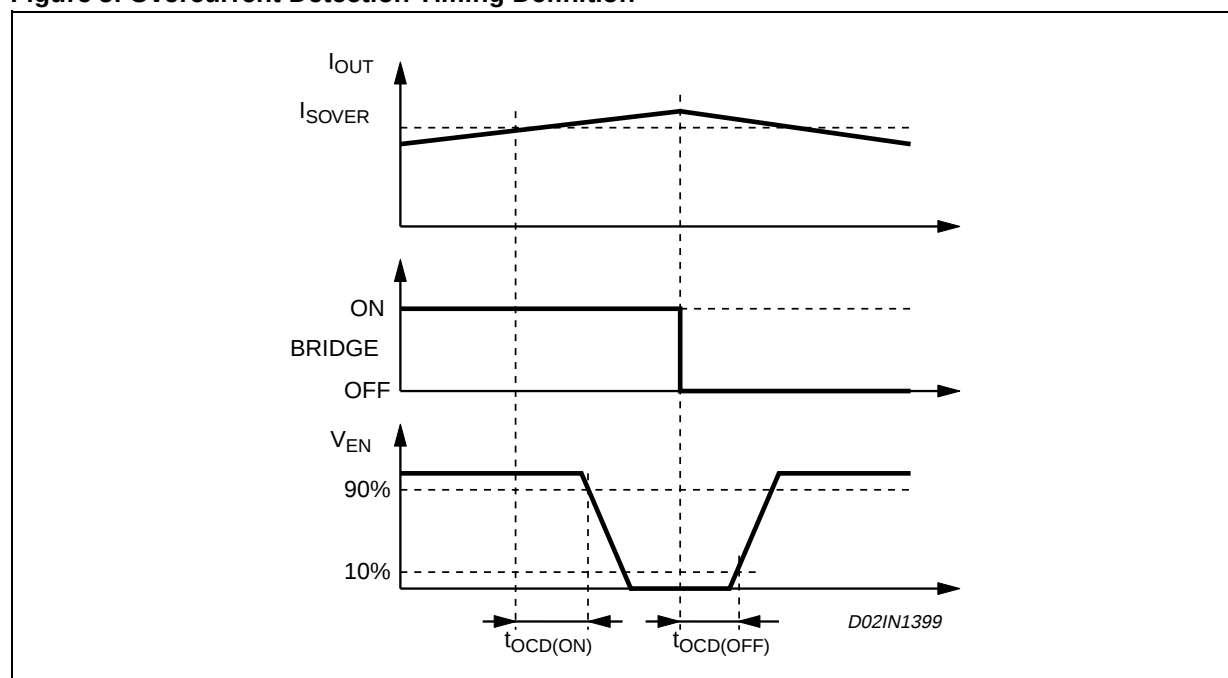


Figure 5. Overcurrent Detection Timing Definition



## CIRCUIT DESCRIPTION

### POWER STAGES and CHARGE PUMP

The L6208 integrates two independent Power MOS Full Bridges. Each Power MOS has an  $R_{DS(ON)} = 0.3\Omega$  (typical value @ 25°C), with intrinsic fast freewheeling diode. Switching patterns are generated by the PWM Current Controller and the Phase Sequence Generator (see below). Cross conduction protection is achieved using a dead time ( $t_{DT} = 1\mu s$  typical value) between the switch off and switch on of two Power MOSFETs in one leg of a bridge.

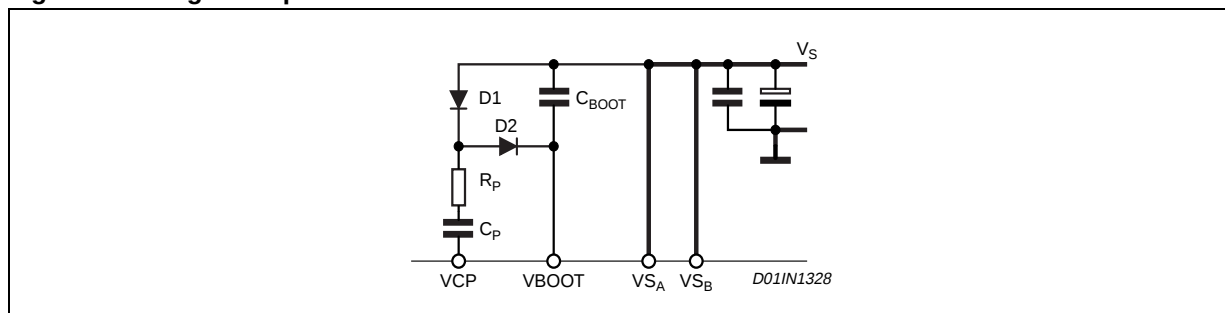
Pins  $VS_A$  and  $VS_B$  MUST be connected together to the supply voltage  $V_S$ . The device operates with a supply voltage in the range from 8V to 52V. It has to be noticed that the  $R_{DS(ON)}$  increases of some percents when the supply voltage is in the range from 8V to 12V (see Fig. 34 and 35).

Using N-Channel Power MOS for the upper transistors in the bridge requires a gate drive voltage above the power supply voltage. The bootstrapped supply voltage  $V_{BOOT}$  is obtained through an internal Oscillator and few external components to realize a charge pump circuit as shown in Figure 6. The oscillator output (VCP) is a square wave at 600KHz (typical) with 10V amplitude. Recommended values/part numbers for the charge pump circuit are shown in Table 1.

Table 1. Charge Pump External Components Values

|            |              |
|------------|--------------|
| $C_{BOOT}$ | 220nF        |
| $C_P$      | 10nF         |
| $R_P$      | 100 $\Omega$ |
| D1         | 1N4148       |
| D2         | 1N4148       |

Figure 6. Charge Pump Circuit



### LOGIC INPUTS

Pins CONTROL, HALF/FULL, CLOCK, RESET and CW/CCW are TTL/CMOS and  $\mu$ C compatible logic inputs. The internal structure is shown in Fig. 7. Typical value for turn-on and turn-off thresholds are respectively  $V_{th(ON)} = 1.8V$  and  $V_{th(OFF)} = 1.3V$ .

Pin EN (Enable) has identical input structure with the exception that the drain of the Overcurrent and thermal protection MOSFET is also connected to this pin. Due to this connection some care needs to be taken in driving this pin. The EN input may be driven in one of two configurations as shown in Fig. 8 or 9. If driven by an open drain (collector) structure, a pull-up resistor  $R_{EN}$  and a capacitor  $C_{EN}$  are connected as shown in Fig. 8. If the driver is a standard Push-Pull structure the resistor  $R_{EN}$  and the capacitor  $C_{EN}$  are connected as shown in Fig. 9. The resistor  $R_{EN}$  should be chosen in the range from  $2.2K\Omega$  to  $180K\Omega$ . Recommended values for  $R_{EN}$  and  $C_{EN}$  are respectively  $100K\Omega$  and  $5.6nF$ . More information on selecting the values is found in the Overcurrent Protection section.

Figure 7. Logic Inputs Internal Structure

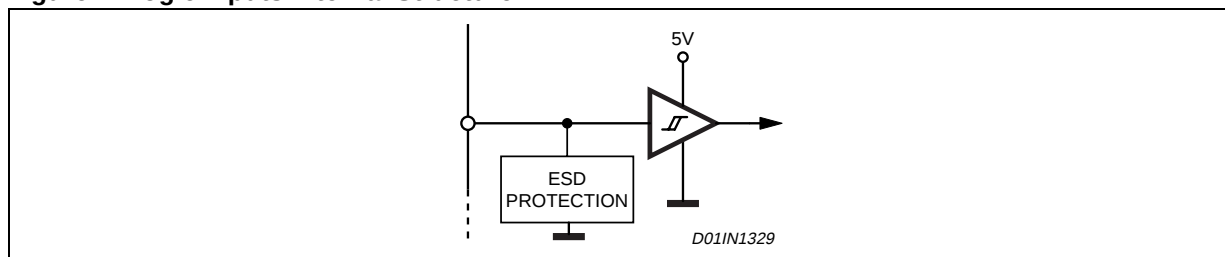


Figure 8. EN Pin Open Collector Driving

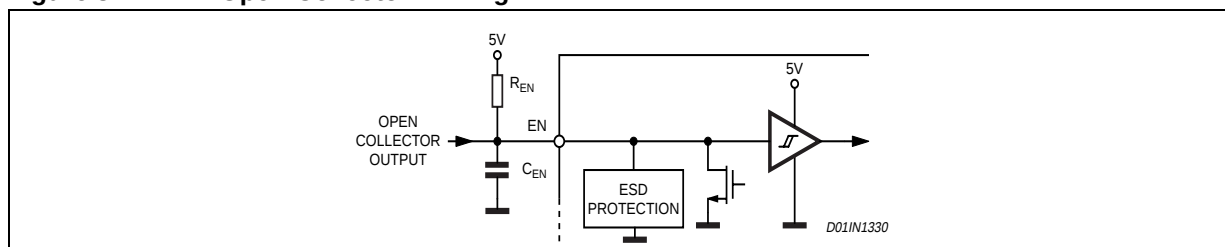


Figure 9. EN Pin Push-Pull Driving

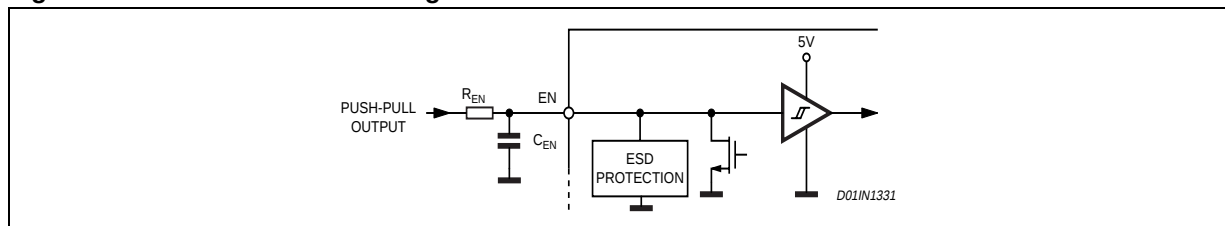




Figure 11. Output Current Regulation Waveforms

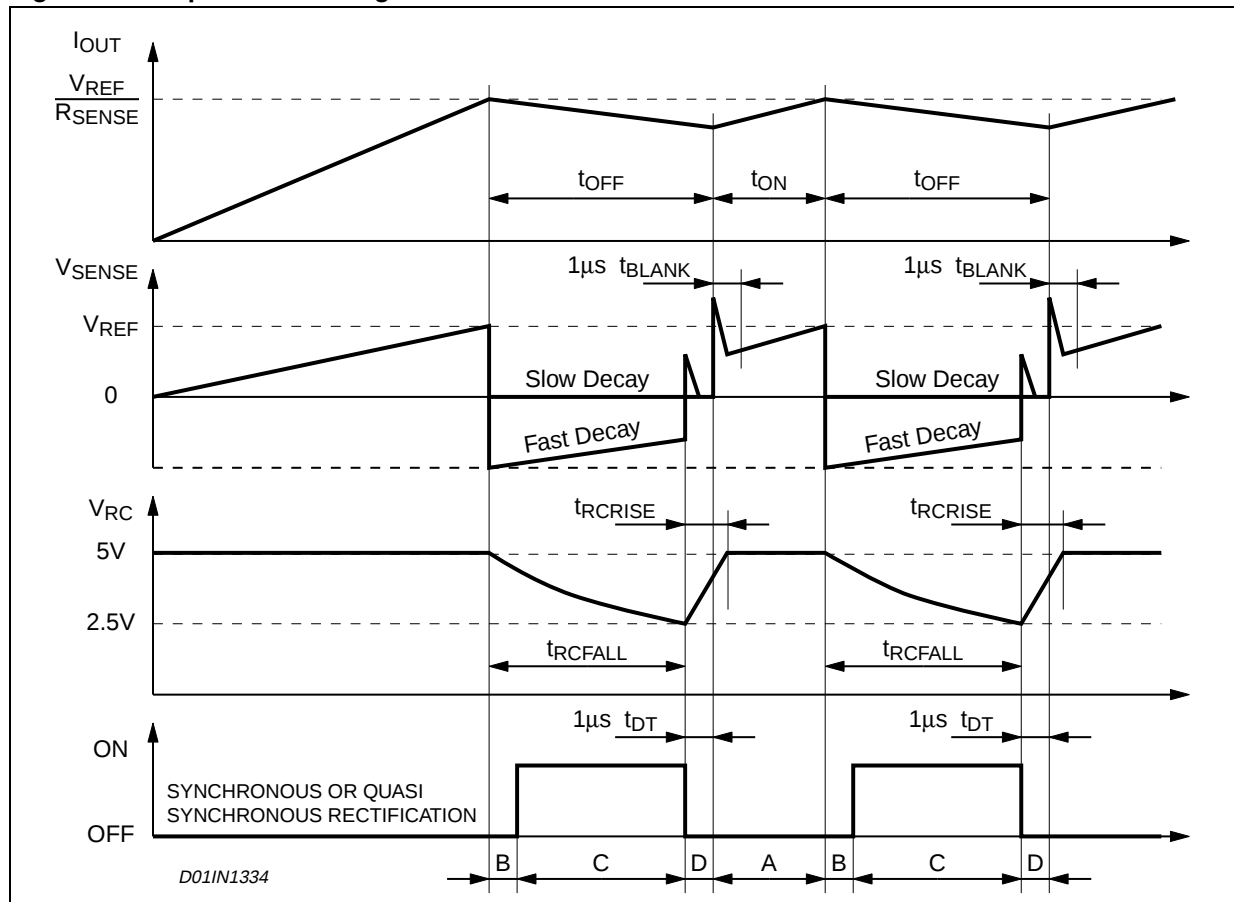


Figure 12 shows the magnitude of the Off Time  $t_{OFF}$  versus  $C_{OFF}$  and  $R_{OFF}$  values. It can be approximately calculated from the equations:

$$t_{RCFALL} = 0.6 \cdot R_{OFF} \cdot C_{OFF}$$

$$t_{OFF} = t_{RCFALL} + t_{DT} = 0.6 \cdot R_{OFF} \cdot C_{OFF} + t_{DT}$$

where  $R_{OFF}$  and  $C_{OFF}$  are the external component values and  $t_{DT}$  is the internally generated Dead Time with:

$$20K\Omega \leq R_{OFF} \leq 100K\Omega$$

$$0.47nF \leq C_{OFF} \leq 100nF$$

$$t_{DT} = 1\mu s \text{ (typical value)}$$

Therefore:

$$t_{OFF(MIN)} = 6.6\mu s$$

$$t_{OFF(MAX)} = 6ms$$

These values allow a sufficient range of  $t_{OFF}$  to implement the drive circuit for most motors.

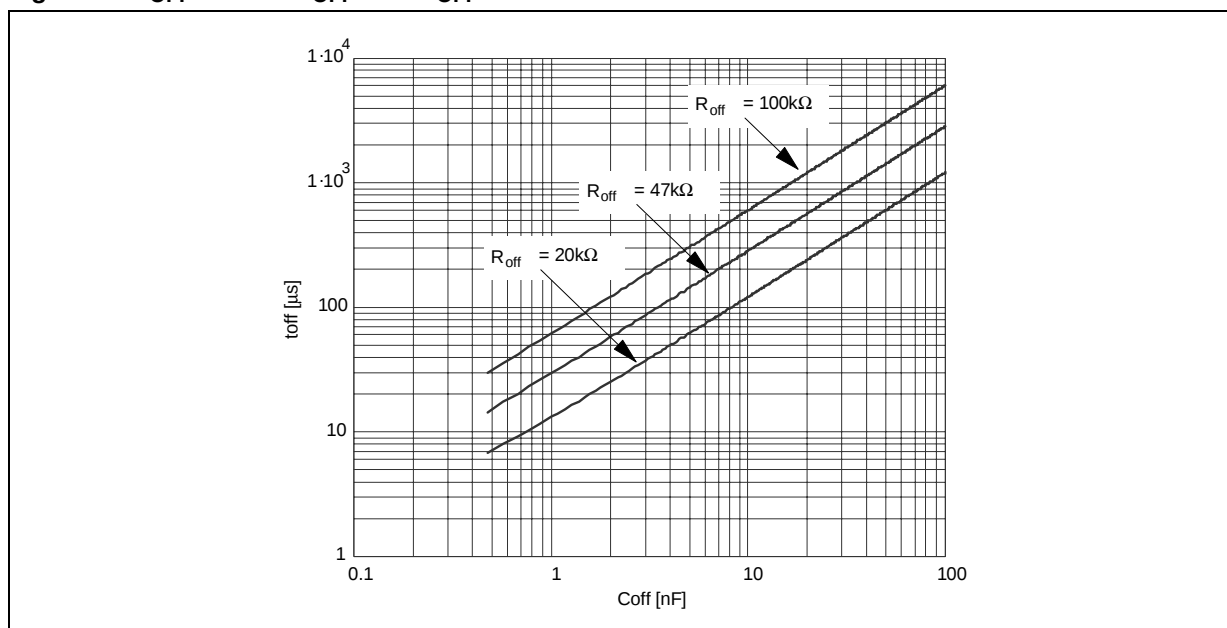
The capacitor value chosen for  $C_{OFF}$  also affects the Rise Time  $t_{RCRISE}$  of the voltage at the pin  $R_{COFF}$ . The Rise Time  $t_{RCRISE}$  will only be an issue if the capacitor is not completely charged before the next time the monostable is triggered. Therefore, the on time  $t_{ON}$ , which depends by motors and supply parameters, has to be bigger than  $t_{RCRISE}$  for allowing a good current regulation by the PWM stage. Furthermore, the on time  $t_{ON}$  can not be smaller than the minimum on time  $t_{ON(MIN)}$ .

$$\begin{cases} t_{ON} > t_{ON(MIN)} = 1.5\mu s \text{ (typ. value)} \\ t_{ON} > t_{RCRISE} - t_{DT} \end{cases}$$

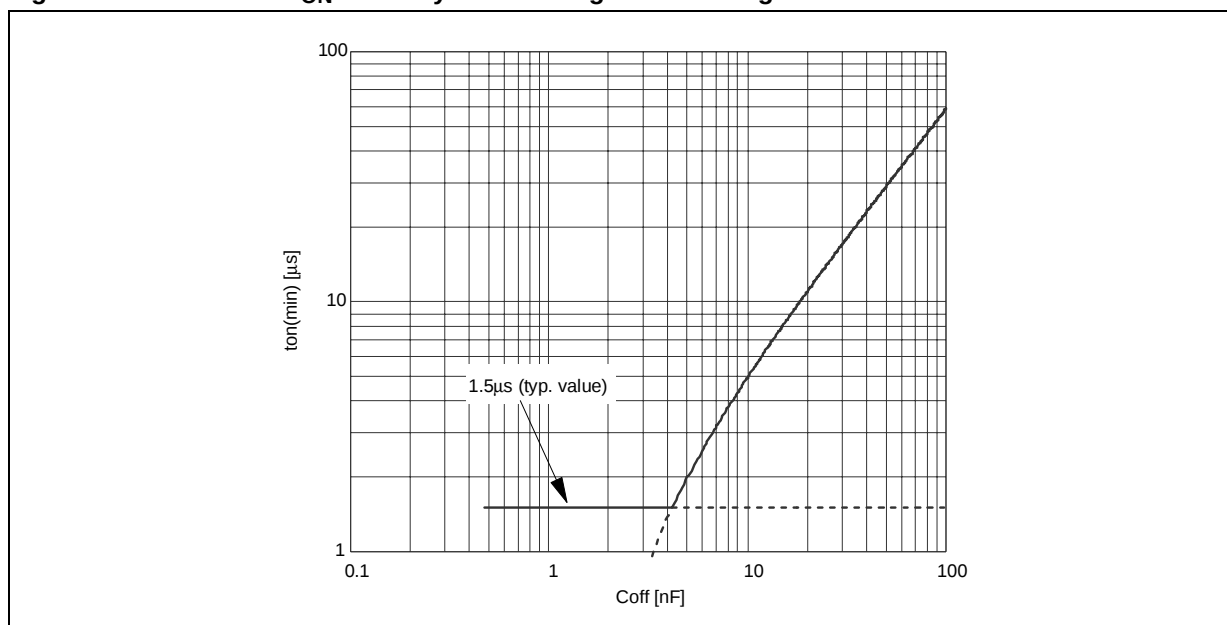
$$t_{RCRISE} = 600 \cdot C_{OFF}$$

Figure 13 shows the lower limit for the on time  $t_{ON}$  for having a good PWM current regulation capacity. It has to be said that  $t_{ON}$  is always bigger than  $t_{ON(MIN)}$  because the device imposes this condition, but it can be smaller than  $t_{RCRISE} - t_{DT}$ . In this last case the device continues to work but the off time  $t_{OFF}$  is not more constant. So, small  $C_{OFF}$  value gives more flexibility for the applications (allows smaller on time and, therefore, higher switching frequency), but, the smaller is the value for  $C_{OFF}$ , the more influential will be the noises on the circuit performance.

**Figure 12.  $t_{OFF}$  versus  $C_{OFF}$  and  $R_{OFF}$**



**Figure 13. Area where  $t_{ON}$  can vary maintaining the PWM regulation.**



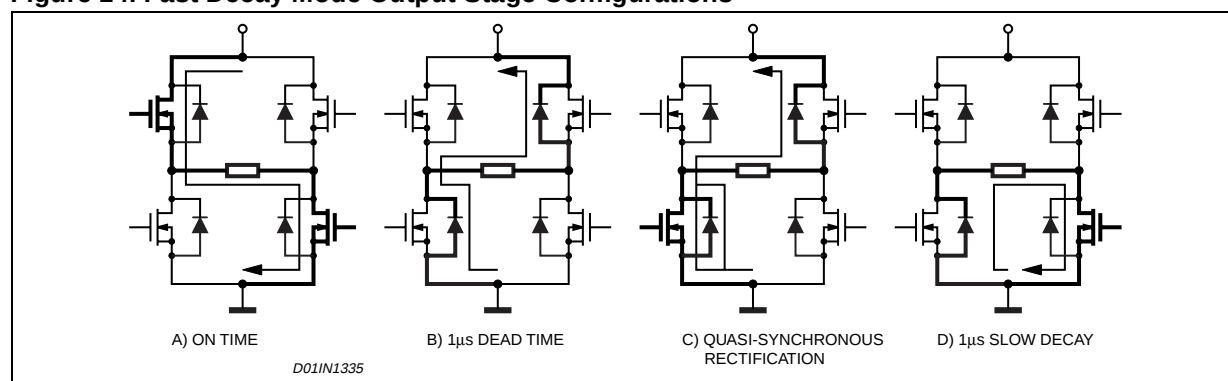
## DECAY MODES

The CONTROL input is used to select the behavior of the bridge during the off time. When the CONTROL pin is low, the Fast Decay mode is selected and both transistors in the bridge are switched off during the off time. When the CONTROL pin is high, the Slow Decay mode is selected and only the low side transistor of the bridge is switched off during the off time.

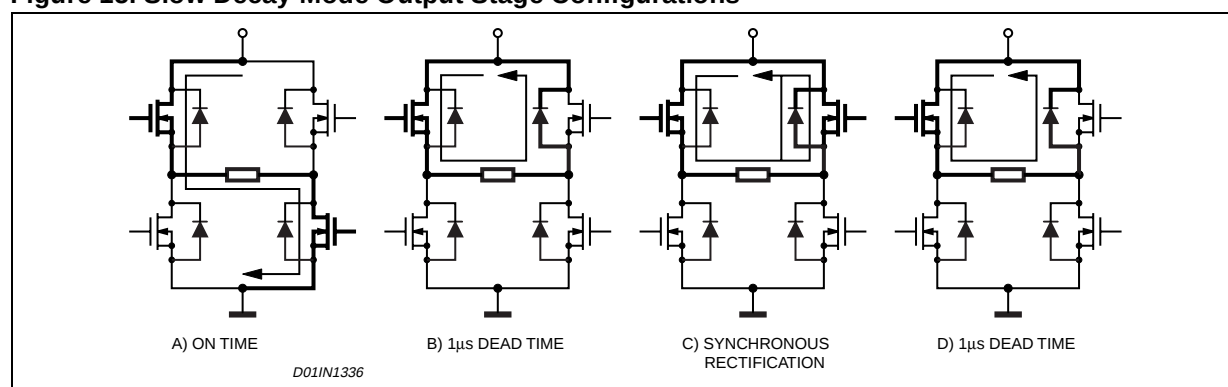
Figure 14 shows the operation of the bridge in the Fast Decay mode. At the start of the off time, both of the power MOS are switched off and the current recirculates through the two opposite free wheeling diodes. The current decays with a high  $di/dt$  since the voltage across the coil is essentially the power supply voltage. After the dead time, the lower power MOS in parallel with the conducting diode is turned on in synchronous rectification mode. In applications where the motor current is low it is possible that the current can decay completely to zero during the off time. At this point if both of the power MOS were operating in the synchronous rectification mode it would then be possible for the current to build in the opposite direction. To prevent this only the lower power MOS is operated in synchronous rectification mode. This operation is called Quasi-Synchronous Rectification Mode. When the monostable times out, the power MOS are turned on again after some delay set by the dead time to prevent cross conduction.

Figure 15 shows the operation of the bridge in the Slow Decay mode. At the start of the off time, the lower power MOS is switched off and the current recirculates around the upper half of the bridge. Since the voltage across the coil is low, the current decays slowly. After the dead time the upper power MOS is operated in the synchronous rectification mode. When the monostable times out, the lower power MOS is turned on again after some delay set by the dead time to prevent cross conduction.

**Figure 14. Fast Decay Mode Output Stage Configurations**



**Figure 15. Slow Decay Mode Output Stage Configurations**



## STEPPING SEQUENCE GENERATION

The phase sequence generator is a state machine that provides the phase and enable inputs for the two bridges to drive a stepper motor in either full step or half step. Two full step modes are possible, the Normal Drive Mode where both phases are energized each step and the Wave Drive Mode where only one phase is energized at a

time. The drive mode is selected by the HALF/FULL input and the current state of the sequence generator as described below. A rising edge of the CLOCK input advances the state machine to the next state. The direction of rotation is set by the CW/CCW input. The RESET input resets the state machine to state.

### HALF STEP MODE

A HIGH logic level on the HALF/FULL input selects Half Step Mode. Figure 16 shows the motor current waveforms and the state diagram for the Phase Sequencer Generator. At Start-Up or after a RESET the Phase Sequencer is at state 1. After each clock pulse the state changes following the sequence 1,2,3,4,5,6,7,8,... if CW/CCW is high (Clockwise movement) or 1,8,7,6,5,4,3,2,... if CW/CCW is low (Counterclockwise movement).

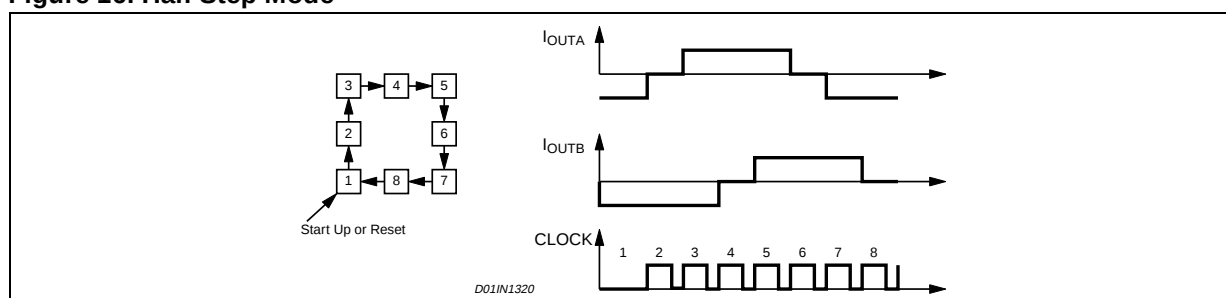
### NORMAL DRIVE MODE (Full-step two-phase-on)

A LOW level on the HALF/FULL input selects the Full Step mode. When the low level is applied when the state machine is at an ODD numbered state the Normal Drive Mode is selected. Figure Fig. 17 shows the motor current waveform state diagram for the state machine of the Phase Sequencer Generator. The Normal Drive Mode can easily be selected by holding the HALF/FULL input low and applying a RESET. AT start -up or after a RESET the State Machine is in state1. While the HALF/FULL input is kept low, state changes following the sequence 1,3,5,7,... if CW/CCW is high (Clockwise movement) or 1,7,5,3,... if CW/CCW is low (Counterclockwise movement).

### WAVE DRIVE MODE (Full-step one-phase-on)

A LOW level on the pin HALF/FULL input selects the Full Step mode. When the low level is applied when the state machine is at an EVEN numbered state the Wave Drive Mode is selected. Figure 18 shows the motor current waveform and the state diagram for the state machine of the Phase Sequence Generator. To enter the Wave Drive Mode the state machine must be in an EVEN numbered state. The most direct method to select the Wave Drive Mode is to first apply a RESET, then while keeping the HALF/FULL input high apply one pulse to the clock input then take the HALF/FULL input low. This sequence first forces the state machine to state 1. The clock pulse, with the HALF/FULL input high advances the state machine from state 1 to either state 2 or 8 depending on the CW/CCW input. Starting from this point, after each clock pulse (rising edge) will advance the state machine following the sequence 2,4,6,8,... if CW/CCW is high (Clockwise movement) or 8,6,4,2,... if CW/CCW is low (Counterclockwise movement).

**Figure 16. Half Step Mode**



**Figure 17. Normal Drive Mode**

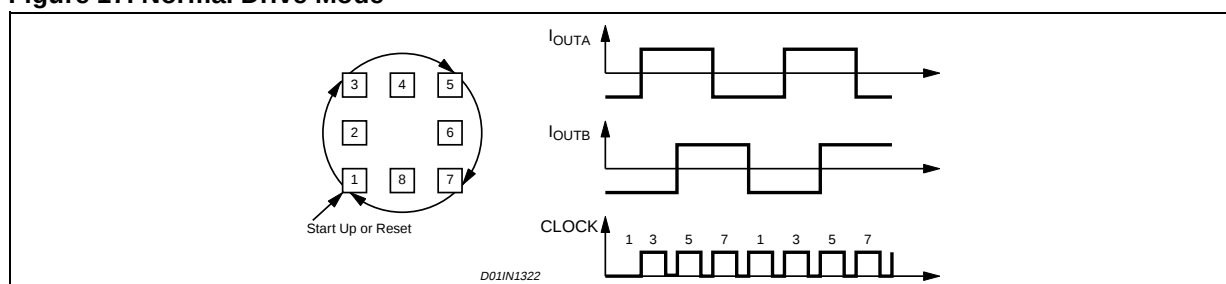
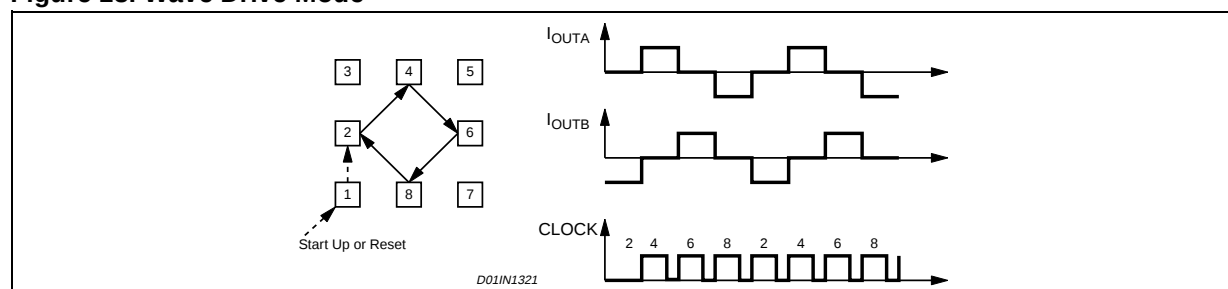


Figure 18. Wave Drive Mode



### NON-DISSIPATIVE OVERCURRENT PROTECTION

The L6208 integrates an Overcurrent Detection Circuit (OCD). This circuit provides protection against a short circuit to ground or between two phases of the bridge. With this internal over current detection, the external current sense resistor normally used and its associated power dissipation are eliminated. Figure 19 shows a simplified schematic of the overcurrent detection circuit.

To implement the over current detection, a sensing element that delivers a small but precise fraction of the output current is implemented with each high side power MOS. Since this current is a small fraction of the output current there is very little additional power dissipation. This current is compared with an internal reference current  $I_{REF}$ . When the output current reaches the detection threshold (typically 5.6A) the OCD comparator signals a fault condition. When a fault condition is detected, the EN pin is pulled below the turn off threshold (1.3V typical) by an internal open drain MOS with a pull down capability of 4mA. By using an external R-C on the EN pin, the off time before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs.

Figure 19. Overcurrent Protection Simplified Schematic

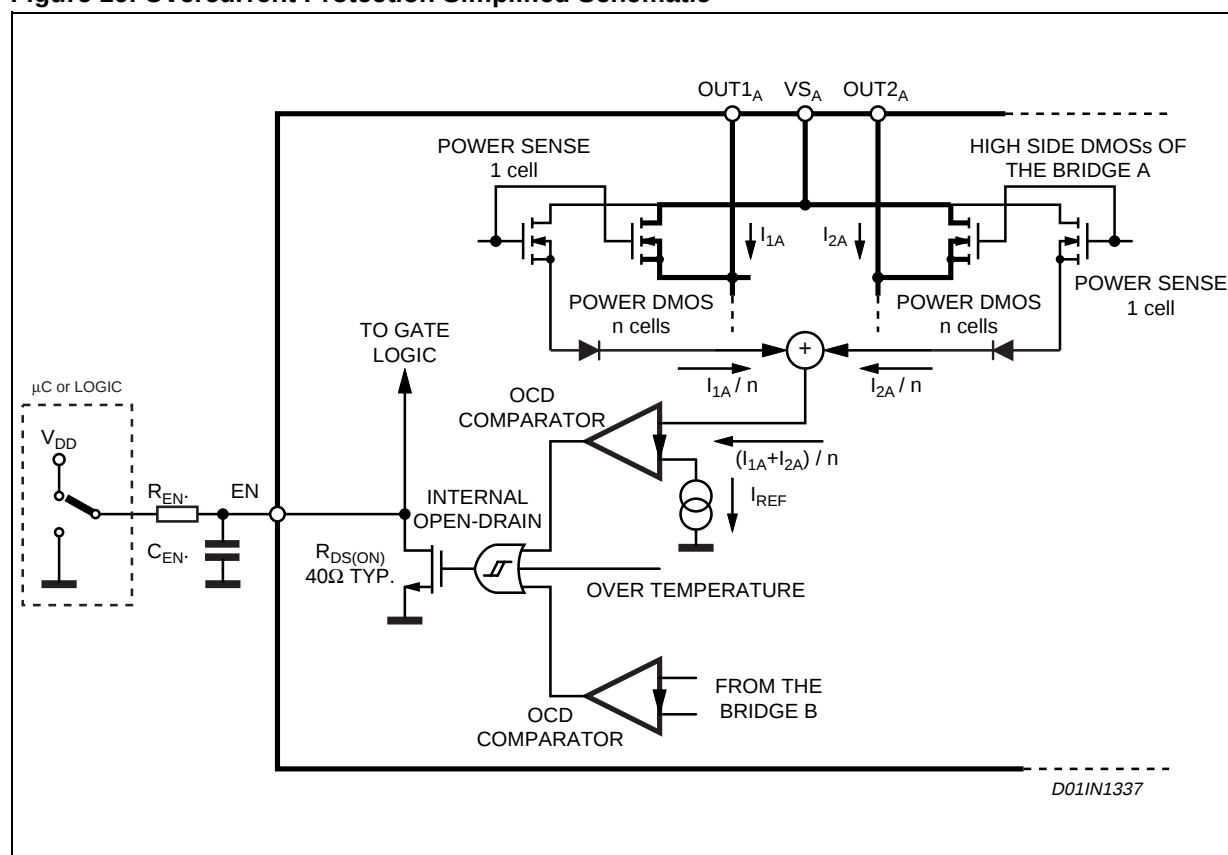


Figure 20 shows the Overcurrent Detection operation. The Disable Time  $t_{\text{DISABLE}}$  before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs. It is affected whether by  $C_{\text{EN}}$  and  $R_{\text{EN}}$  values and its magnitude is reported in Figure 21. The Delay Time  $t_{\text{DELAY}}$  before turning off the bridge when an overcurrent has been detected depends only by  $C_{\text{EN}}$  value. Its magnitude is reported in Figure 22.

$C_{\text{EN}}$  is also used for providing immunity to pin EN against fast transient noises. Therefore the value of  $C_{\text{EN}}$  should be chosen as big as possible according to the maximum tolerable Delay Time and the  $R_{\text{EN}}$  value should be chosen according to the desired Disable Time.

The resistor  $R_{\text{EN}}$  should be chosen in the range from 2.2K $\Omega$  to 180K $\Omega$ . Recommended values for  $R_{\text{EN}}$  and  $C_{\text{EN}}$  are respectively 100K $\Omega$  and 5.6nF that allow obtaining 200 $\mu\text{s}$  Disable Time.

**Figure 20. Overcurrent Protection Waveforms**

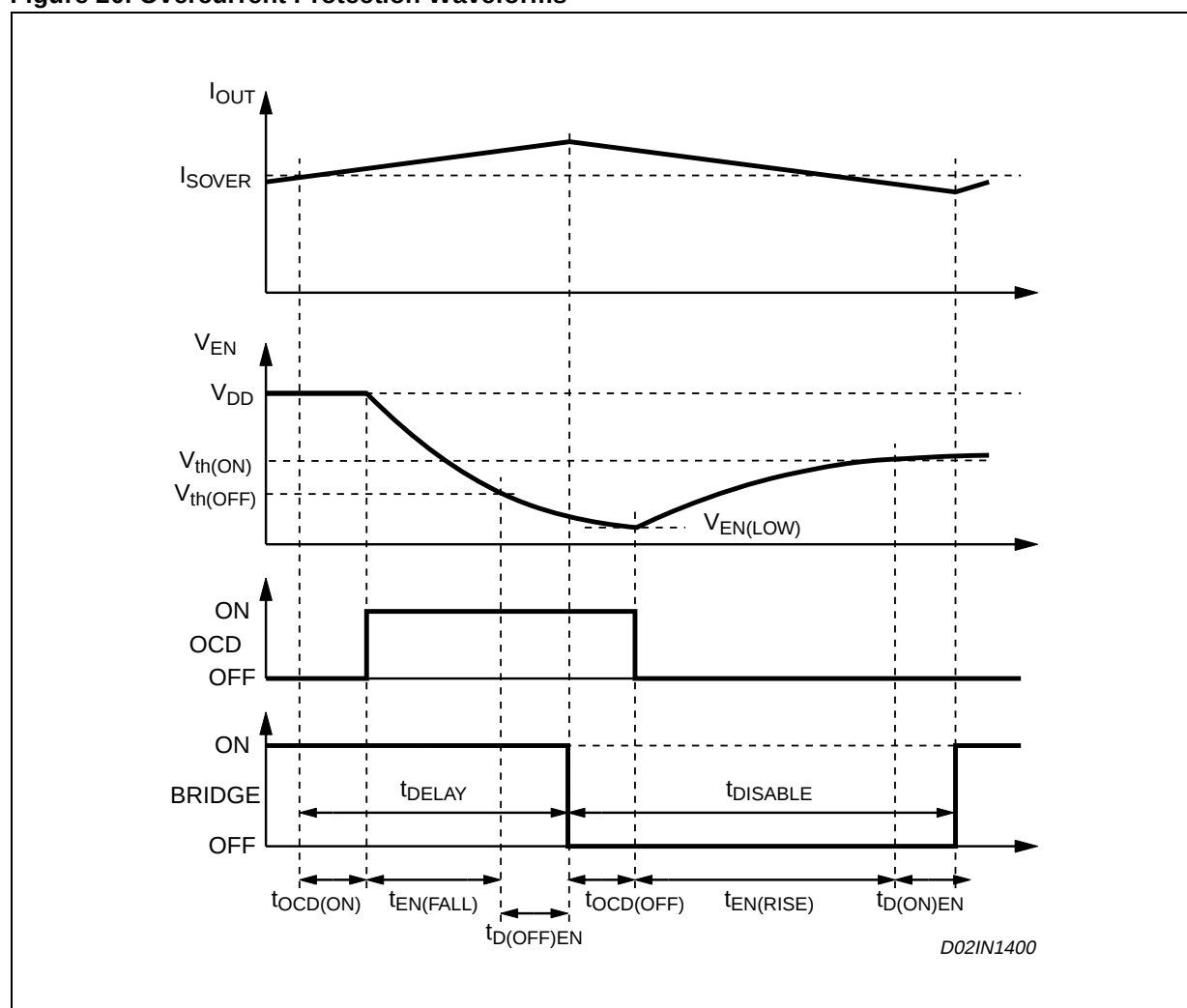
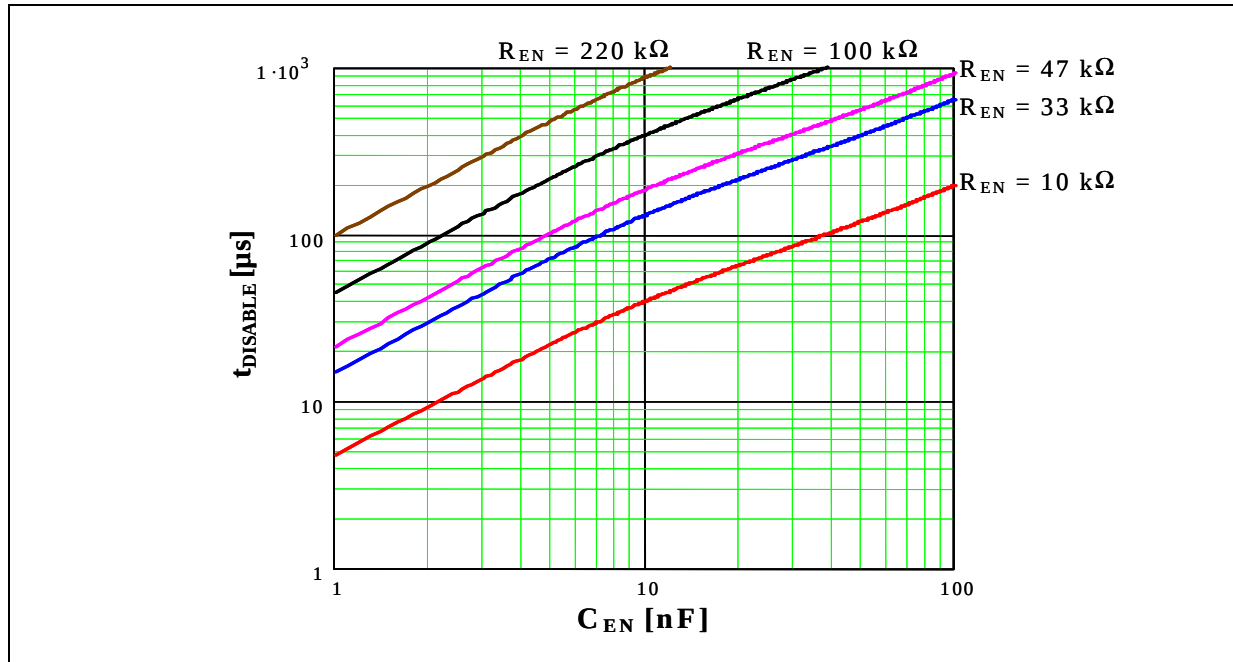
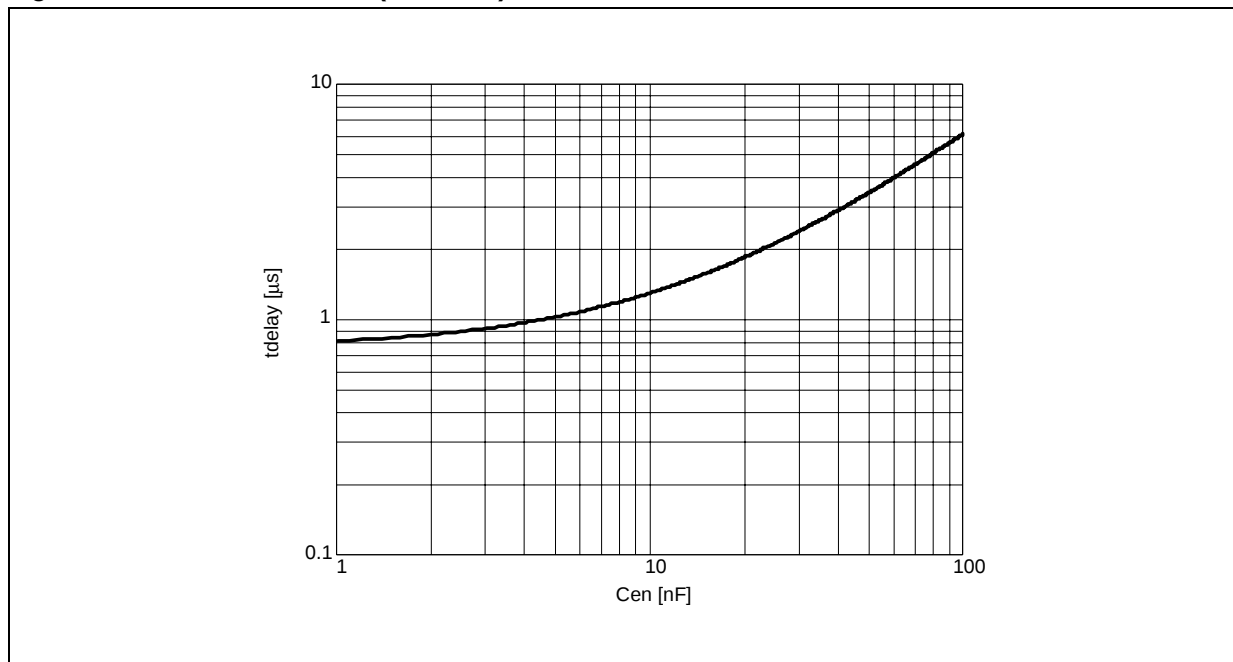


Figure 21.  $t_{\text{DISABLE}}$  versus  $C_{\text{EN}}$  and  $R_{\text{EN}}$  ( $V_{\text{DD}} = 5\text{V}$ ).Figure 22.  $t_{\text{DELAY}}$  versus  $C_{\text{EN}}$  ( $V_{\text{DD}} = 5\text{V}$ ).

### THERMAL PROTECTION

In addition to the Overcurrent Protection, the L6208 integrates a Thermal Protection for preventing the device destruction in case of junction over temperature. It works sensing the die temperature by means of a sensible element integrated in the die. The device switch-off when the junction temperature reaches 165°C (typ. value) with 15°C hysteresis (typ. value).

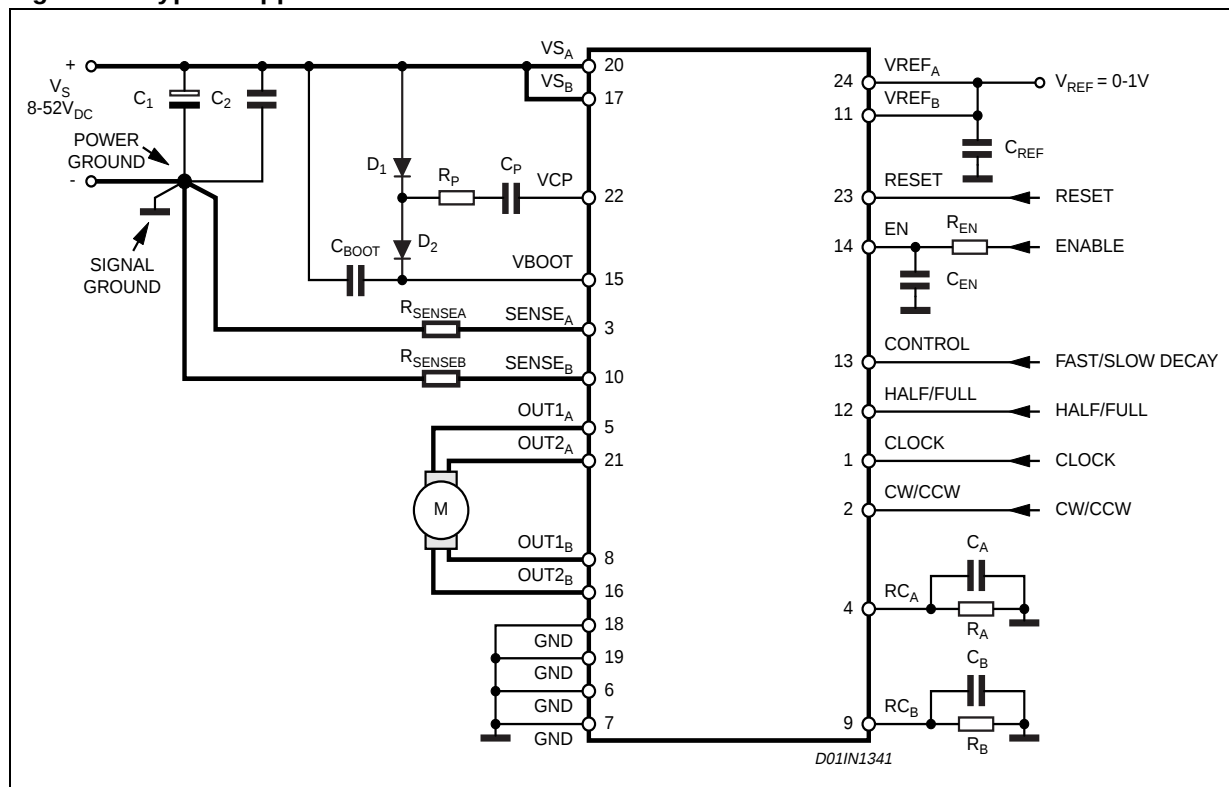
### APPLICATION INFORMATION

A typical Bipolar Stepper Motor Driver application using L6208 is shown in Fig. 23. Typical component values for the application are shown in Table 2. A high quality ceramic capacitor in the range of 100 to 200 nF should be placed between the power pins ( $VS_A$  and  $VS_B$ ) and ground near the L6208 to improve the high frequency filtering on the power supply and reduce high frequency transients generated by the switching. The capacitor connected from the EN input to ground sets the shut down time when an over current is detected (see Overcurrent Protection). The two current sensing inputs ( $SENSE_A$  and  $SENSE_B$ ) should be connected to the sensing resistors with a trace length as short as possible in the layout. The sense resistors should be non-inductive resistors to minimize the di/dt transients across the resistor. To increase noise immunity, unused logic pins (except EN) are best connected to 5V (High Logic Level) or GND (Low Logic Level) (see pin description). It is recommended to keep Power Ground and Signal Ground separated on PCB.

**Table 2. Component Values for Typical Application**

|            |             |               |               |
|------------|-------------|---------------|---------------|
| $C_1$      | 100 $\mu$ F | $D_1$         | 1N4148        |
| $C_2$      | 100nF       | $D_2$         | 1N4148        |
| $C_A$      | 1nF         | $R_A$         | 39K $\Omega$  |
| $C_B$      | 1nF         | $R_B$         | 39K $\Omega$  |
| $C_{BOOT}$ | 220nF       | $R_{EN}$      | 100K $\Omega$ |
| $C_P$      | 10nF        | $R_P$         | 100 $\Omega$  |
| $C_{EN}$   | 5.6nF       | $R_{SENSE_A}$ | 0.3 $\Omega$  |
| $C_{REF}$  | 68nF        | $R_{SENSE_B}$ | 0.3 $\Omega$  |

**Figure 23. Typical Application**



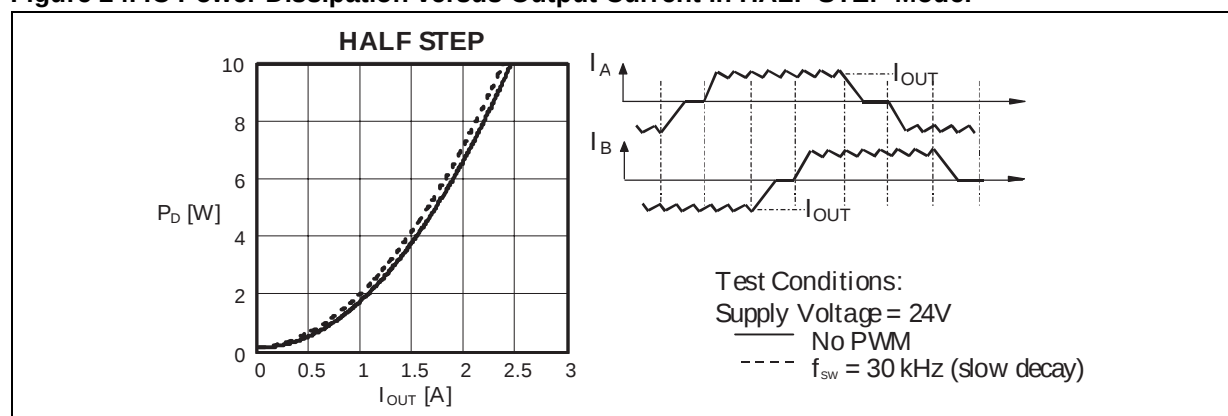
### Output Current Capability and IC Power Dissipation

In Fig. 24, 25, 26 and 27 are shown the approximate relation between the output current and the IC power dissipation using PWM current control driving a two-phase stepper motor, for different driving sequences:

- HALF STEP mode (Fig. 24) in which alternately one phase / two phases are energized.
- NORMAL DRIVE (FULL-STEP TWO PHASE ON) mode (Fig. 25) in which two phases are energized during each step.
- WAVE DRIVE (FULL-STEP ONE PHASE ON) mode (Fig. 26) in which only one phase is energized at each step.
- MICROSTEPPING mode (Fig. 27), in which the current follows a sine-wave profile, provided through the  $V_{ref}$  pins.

For a given output current and driving sequence the power dissipated by the IC can be easily evaluated, in order to establish which package should be used and how large must be the on-board copper dissipating area to guarantee a safe operating junction temperature (125°C maximum).

**Figure 24. IC Power Dissipation versus Output Current in HALF STEP Mode.**



**Figure 25. IC Power Dissipation versus Output Current in NORMAL Mode (full step two phase on).**

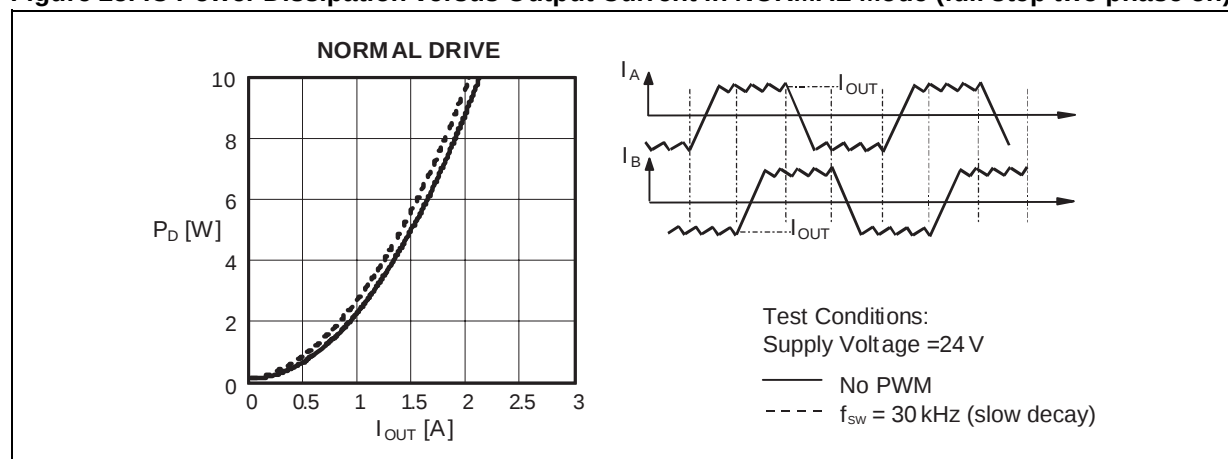


Figure 26. IC Power Dissipation versus Output Current in WAVE Mode (full step one phase on).

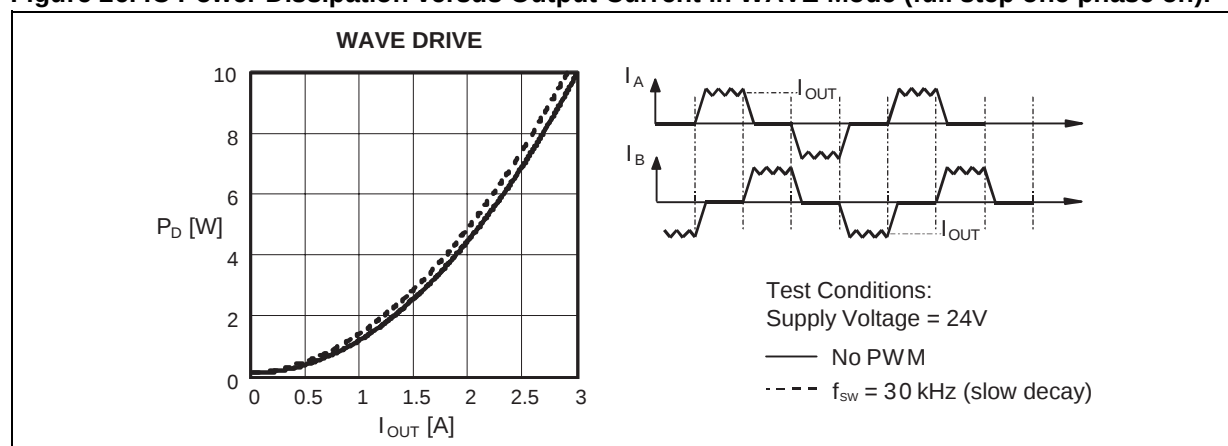
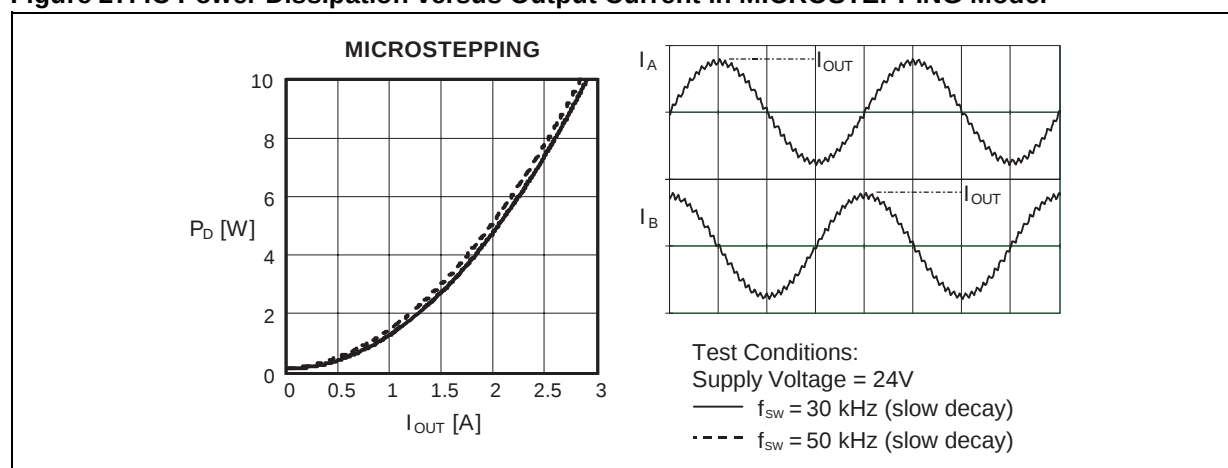


Figure 27. IC Power Dissipation versus Output Current in MICROSTEPPING Mode.



### Thermal Management

In most applications the power dissipation in the IC is the main factor that sets the maximum current that can be delivered by the device in a safe operating condition. Therefore, it has to be taken into account very carefully. Besides the available space on the PCB, the right package should be chosen considering the power dissipation. Heat sinking can be achieved using copper on the PCB with proper area and thickness. Figures 28, 29 and 30 show the Junction-to-Ambient Thermal Resistance values for the PowerSO36, PowerDIP24 and SO24 packages.

For instance, using a PowerSO package with copper slug soldered on a 1.5mm copper thickness FR4 board with 6cm<sup>2</sup> dissipating footprint (copper thickness of 35μm), the  $R_{th(j-amb)}$  is about 35°C/W. Fig. 31 shows mounting methods for this package. Using a multi-layer board with vias to a ground plane, thermal impedance can be reduced down to 15°C/W.

Figure 28. PowerSO36 Junction-Ambient Thermal Resistance versus On-Board Copper Area.

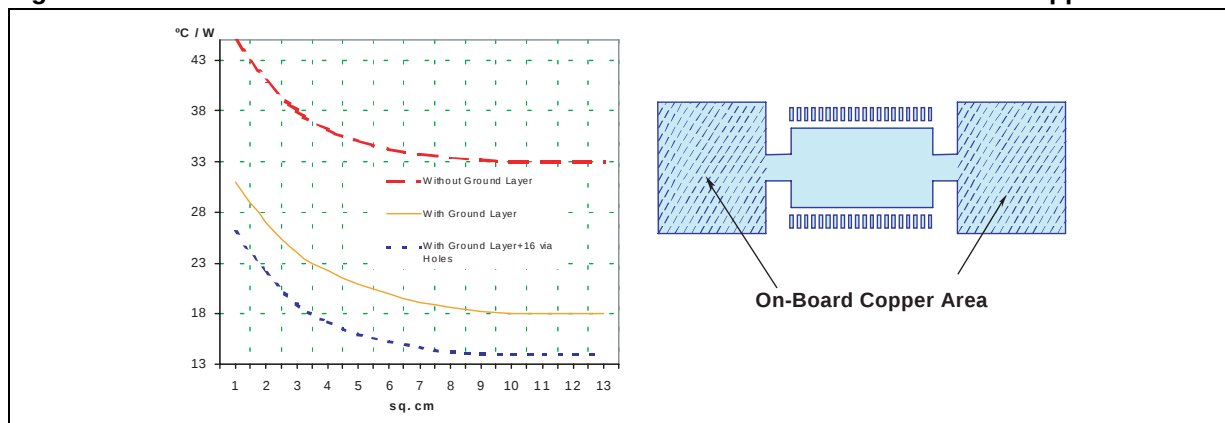


Figure 29. PowerDIP24 Junction-Ambient Thermal Resistance versus On-Board Copper Area.

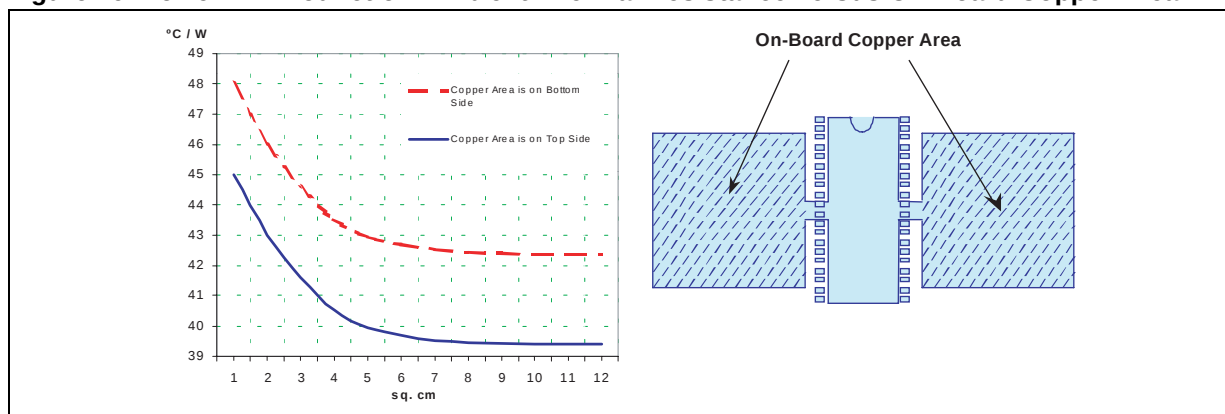


Figure 30. SO24 Junction-Ambient Thermal Resistance versus On-Board Copper Area.

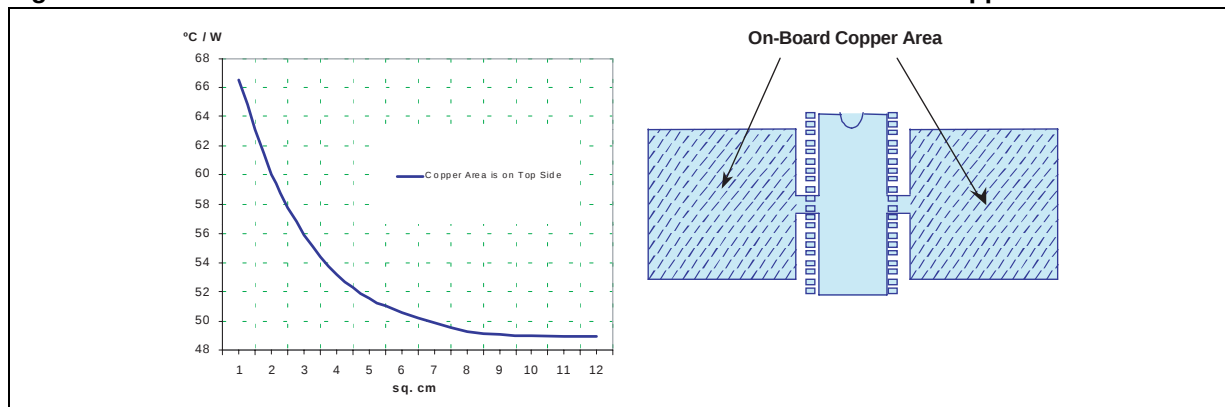
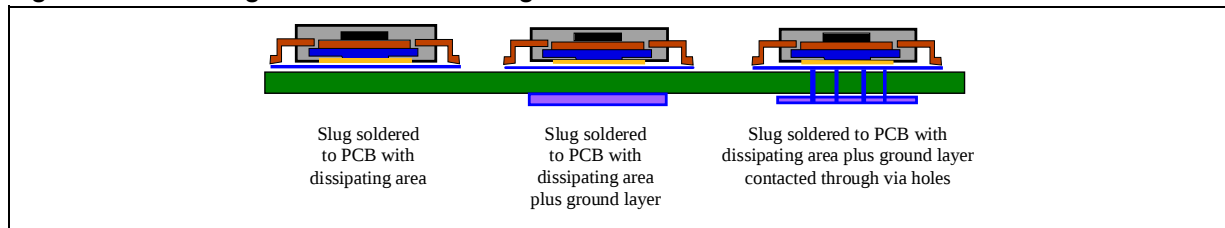
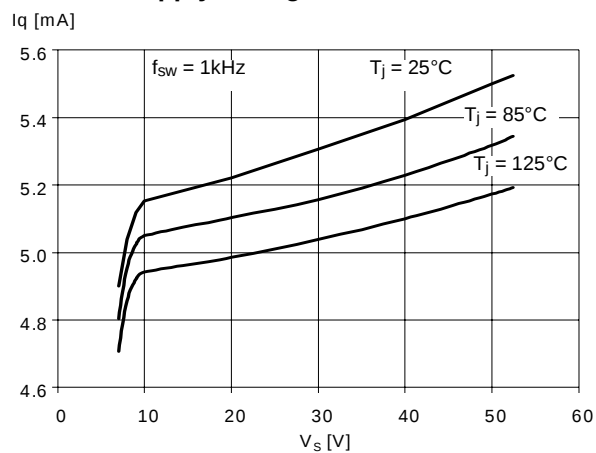


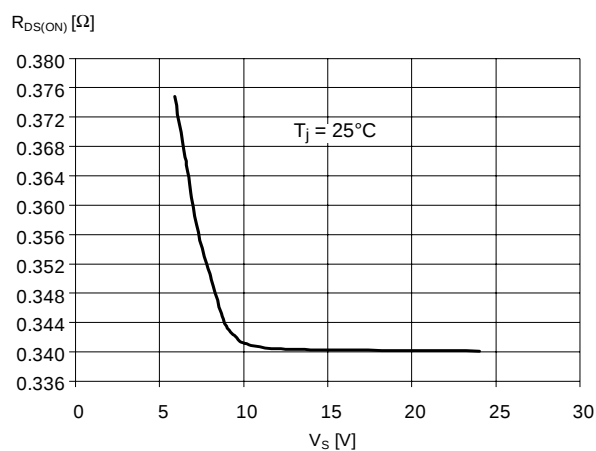
Figure 31. Mounting the PowerSO Package.



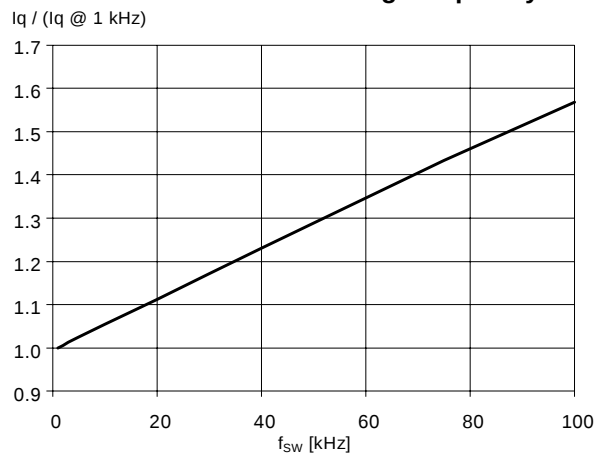
**Figure 32. Typical Quiescent Current vs. Supply Voltage**



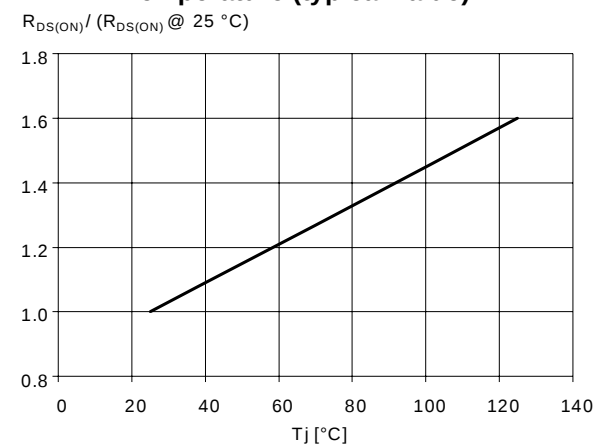
**Figure 35. Typical High-Side  $R_{DS(ON)}$  vs. Supply Voltage**



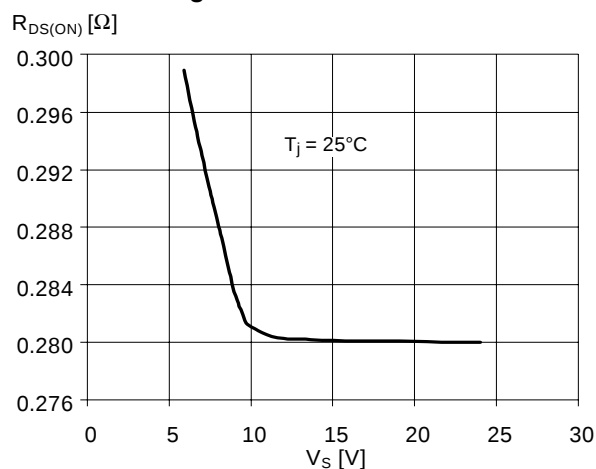
**Figure 33. Normalized Typical Quiescent Current vs. Switching Frequency**



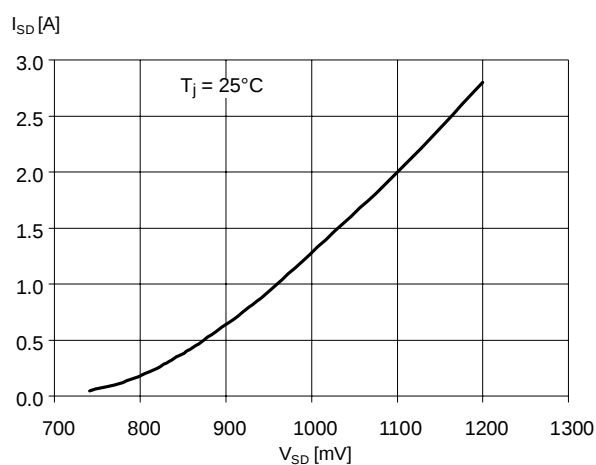
**Figure 36. Normalized  $R_{DS(ON)}$  vs. Junction Temperature (typical value)**



**Figure 34. Typical Low-Side  $R_{DS(ON)}$  vs. Supply Voltage**



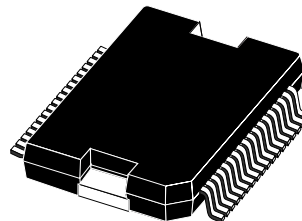
**Figure 37. Typical Drain-Source Diode Forward ON Characteristic**



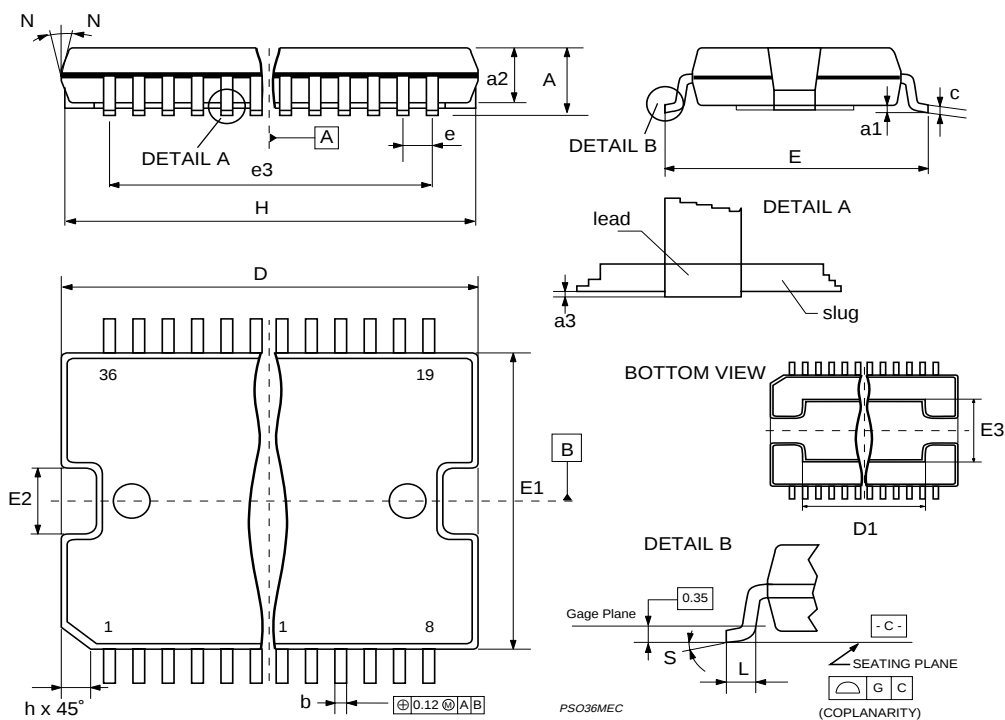
| DIM.   | mm        |       |       | inch  |        |       |
|--------|-----------|-------|-------|-------|--------|-------|
|        | MIN.      | TYP.  | MAX.  | MIN.  | TYP.   | MAX.  |
| A      |           |       | 3.60  |       |        | 0.141 |
| a1     | 0.10      |       | 0.30  | 0.004 |        | 0.012 |
| a2     |           |       | 3.30  |       |        | 0.130 |
| a3     | 0         |       | 0.10  | 0     |        | 0.004 |
| b      | 0.22      |       | 0.38  | 0.008 |        | 0.015 |
| c      | 0.23      |       | 0.32  | 0.009 |        | 0.012 |
| D (1)  | 15.80     |       | 16.00 | 0.622 |        | 0.630 |
| D1     | 9.40      |       | 9.80  | 0.370 |        | 0.385 |
| E      | 13.90     |       | 14.50 | 0.547 |        | 0.570 |
| e      |           | 0.65  |       |       | 0.0256 |       |
| e3     |           | 11.05 |       |       | 0.435  |       |
| E1 (1) | 10.90     |       | 11.10 | 0.429 |        | 0.437 |
| E2     |           |       | 2.90  |       |        | 0.114 |
| E3     | 5.80      |       | 6.20  | 0.228 |        | 0.244 |
| E4     | 2.90      |       | 3.20  | 0.114 |        | 0.126 |
| G      | 0         |       | 0.10  | 0     |        | 0.004 |
| H      | 15.50     |       | 15.90 | 0.610 |        | 0.626 |
| h      |           |       | 1.10  |       |        | 0.043 |
| L      | 0.80      |       | 1.10  | 0.031 |        | 0.043 |
| N      | 10°(max.) |       |       |       |        |       |
| S      | 8 °(max.) |       |       |       |        |       |

(1): "D" and "E1" do not include mold flash or protrusions  
- Mold flash or protrusions shall not exceed 0.15mm (0.006 inch)  
- Critical dimensions are "a3", "E" and "G".

## OUTLINE AND MECHANICAL DATA

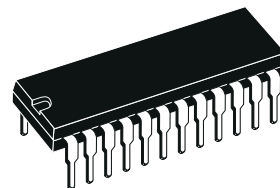


## PowerSO36

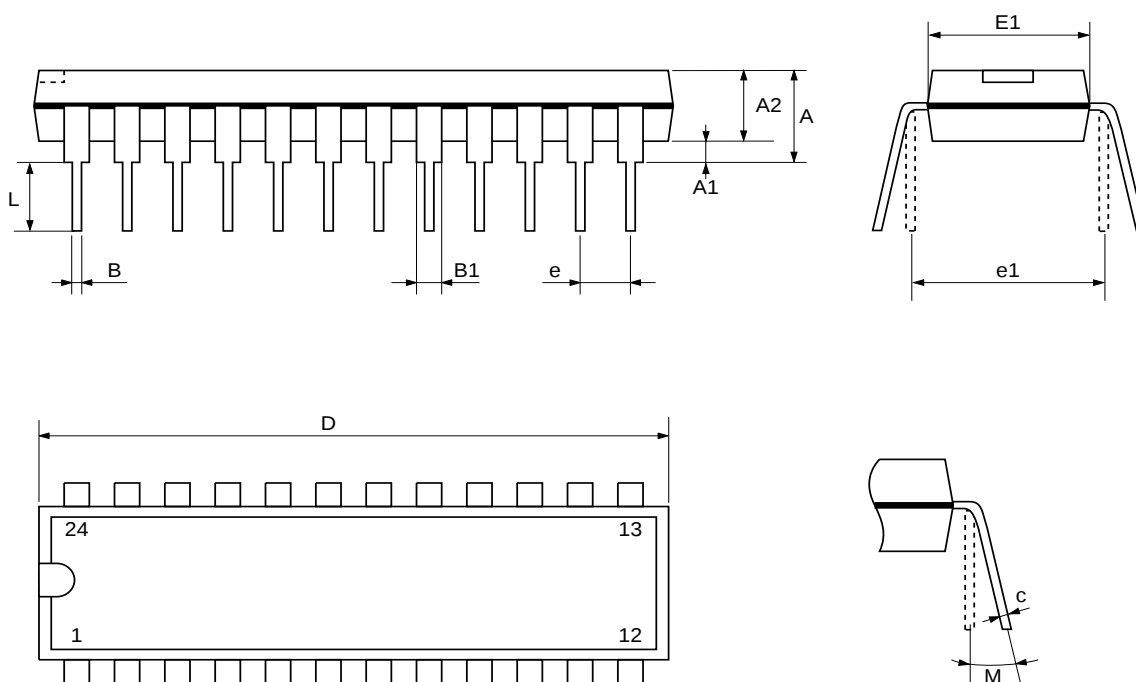


| DIM. | mm               |       |       | inch  |       |       |
|------|------------------|-------|-------|-------|-------|-------|
|      | MIN.             | TYP.  | MAX.  | MIN.  | TYP.  | MAX.  |
| A    |                  |       | 4.320 |       |       | 0.170 |
| A1   | 0.380            |       |       | 0.015 |       |       |
| A2   |                  | 3.300 |       |       | 0.130 |       |
| B    | 0.410            | 0.460 | 0.510 | 0.016 | 0.018 | 0.020 |
| B1   | 1.400            | 1.520 | 1.650 | 0.055 | 0.060 | 0.065 |
| c    | 0.200            | 0.250 | 0.300 | 0.008 | 0.010 | 0.012 |
| D    | 31.62            | 31.75 | 31.88 | 1.245 | 1.250 | 1.255 |
| E    | 7.620            |       | 8.260 | 0.300 |       | 0.325 |
| e    |                  | 2.54  |       |       | 0.100 |       |
| E1   | 6.350            | 6.600 | 6.860 | 0.250 | 0.260 | 0.270 |
| e1   |                  | 7.620 |       |       | 0.300 |       |
| L    | 3.180            |       | 3.430 | 0.125 |       | 0.135 |
| M    | 0° min, 15° max. |       |       |       |       |       |

## OUTLINE AND MECHANICAL DATA



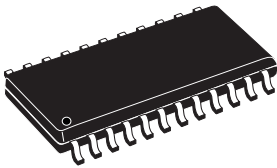
**Powerdip 24**



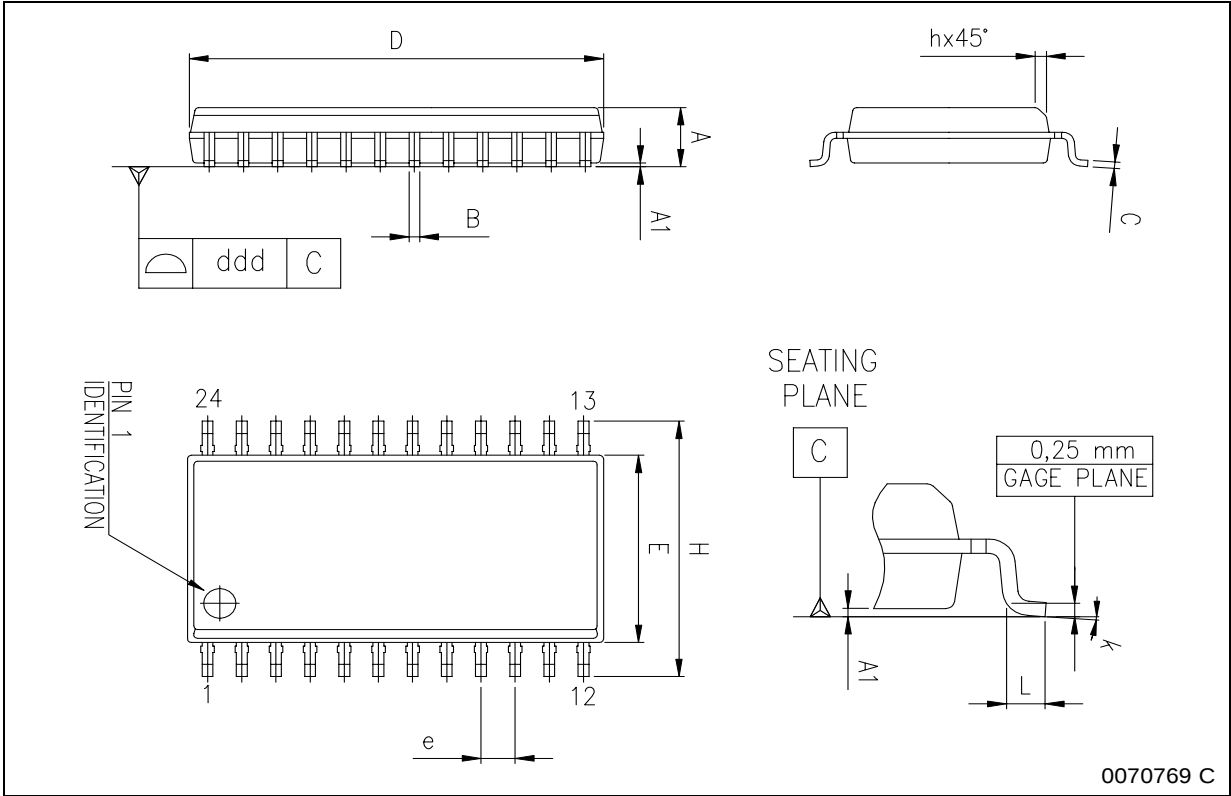
| DIM.                                                                                                                                            | mm                   |      |       | inch  |       |       |
|-------------------------------------------------------------------------------------------------------------------------------------------------|----------------------|------|-------|-------|-------|-------|
|                                                                                                                                                 | MIN.                 | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A                                                                                                                                               | 2.35                 |      | 2.65  | 0.093 |       | 0.104 |
| A1                                                                                                                                              | 0.10                 |      | 0.30  | 0.004 |       | 0.012 |
| B                                                                                                                                               | 0.33                 |      | 0.51  | 0.013 |       | 0.200 |
| C                                                                                                                                               | 0.23                 |      | 0.32  | 0.009 |       | 0.013 |
| D <sup>(1)</sup>                                                                                                                                | 15.20                |      | 15.60 | 0.598 |       | 0.614 |
| E                                                                                                                                               | 7.40                 |      | 7.60  | 0.291 |       | 0.299 |
| e                                                                                                                                               |                      | 1.27 |       |       | 0.050 |       |
| H                                                                                                                                               | 10.0                 |      | 10.65 | 0.394 |       | 0.419 |
| h                                                                                                                                               | 0.25                 |      | 0.75  | 0.010 |       | 0.030 |
| L                                                                                                                                               | 0.40                 |      | 1.27  | 0.016 |       | 0.050 |
| k                                                                                                                                               | 0° (min.), 8° (max.) |      |       |       |       |       |
| ddd                                                                                                                                             |                      |      | 0.10  |       |       | 0.004 |
| (1) "D" dimension does not include mold flash, protusions or gate burrs. Mold flash, protusions or gate burrs shall not exceed 0.15mm per side. |                      |      |       |       |       |       |

**OUTLINE AND  
MECHANICAL DATA**

Weight: 0.60gr



**SO24**



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